

Superconducting nanostructures fabricated with the STM

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(Dated: February 2, 2008)

The properties of nanoscopic superconducting structures fabricated with a scanning tunnelling microscope are reviewed, with emphasis on the effects of high magnetic fields. These systems include the smallest superconducting junctions which can be fabricated, and they are a unique laboratory where to study superconductivity under extreme conditions. The review covers a variety of recent experimental results on these systems, highlighting their unusual transport properties, and theoretical models developed for their understanding.

PACS numbers: 68, 73.22.-f, 73.63.-b, 73.40.-c, 74.45.+c, 74.50.+r, 74.78.-w

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I. INTRODUCTION

Soon after the transcendental discovery by Meissner of the perfect diamagnetism[1], as one of the characteristic features of the superconducting state, the London brothers published in 1935 an article entitled "The electromagnetic equations of the superconductor"[2]. This article contains the well known London theory, which provided the first important approach to our macroscopic understanding of this phenomenon. Very soon one of the brothers, Heinz London, concluded from the theory that "a very small superconductor should have a much higher magnetic threshold value than a bulky one"[3]. R.B. Pontius confirmed this prediction experimentally two years later[4, 5]. In 1939 E.T.S. Appleyard et al. [6] found an increase of the magnetic threshold up to more than twenty times the bulk critical field in mercury films as thin as 57nm. D. Shoenberg[7] observed this effect by measuring the magnetic susceptibility of very fine-grained preparations of colloidal mercury in 1940. From then to now, there have been many important developments both in theory and experiment, including several milestones such as the Ginzburg-Landau (G-L) theory[8], the microscopic BCS theory[9], the Josephson effects[10], the type II superconductors[11] and the discovery of high T_c superconducting oxides[12]. G-L theory has proven itself as a very important tool which separates superconductors into two types (I and II), depending on their response to external magnetic fields. Abrikosov predicted[11] the real existence of type II superconductors, with the characteristic mixed or vortex state present in a wide range of magnetic fields. Tinkham[13] pointed out that sufficiently thin films of any material should exist in the mixed state even if thicker specimens of the same material exhibit a type I behavior. This vortex state was visualized later on in magnetic decoration experiments[14, 15].

Today superconductivity is one of the most flourishing fields of condensed matter physics, showing many new interesting developments. A recent one is the reduction of the dimensions of the superconducting samples towards controlled three dimensional mesoscopic structures. Electron lithography allows to pattern different types of superconducting structures with all their dimensions of the same order or smaller than the magnetic penetration depth of the bulk material[16, 17, 18]. Many experiments and theoretical[19, 20] developments on mesoscopic superconductivity have been made, unravelling new physics related to the confinement of the condensate. Experiments with single small particles[21], thin wires[22, 23], carbon nanotubes[24, 25], or DNA molecules[26, 27, 28] have been reported. Very clever solutions have been given to the difficult problem of the contacts (see e.g. [27]), although it remains one of the main limitations in the operation of these small systems[29, 30].

The invention of the scanning tunnelling microscope[31], STM, has been a breakthrough towards our control of the nanoworld. Following this invention, several tools have been developed extending the initial STM capabilities. Atomic force microscopy [32] has proven to be a powerful tool to investigate both fundamental problems and others with extraordinary technological importance, such as friction, wear or fracture. Imaginative combinations of the working principles of both techniques have promoted new tools for specific experiments. Among them, we highlight the results by Rubio-Bollinger et al.[33], that were able to measure force and conductance simultaneously, extracting one atom after the other from a surface, and creating the smallest and thinnest arrangement of atoms ever made, an atomic chain. Magnetic force microscopy [34] and scanning Hall probe microscopy[35] are other useful members of this toolkit, whose main achievements rest on the impressive control of the displacements that can be done through the piezoelectric deformation of some ceramic materials. This control is magnified at low temperatures where atomic mobility is very low and the creep effect in the piezoelectric ceramics is also reduced to a very low level[36]. There are many relevant achievements in condensed matter physics that have appeared in the twenty years span since the STM invention. One of these, related to the main topic of this review, was the observation of an atomic jump to contact when a metallic atomically sharp tip was carefully approached to a sample of the same material[37]. After this pioneering experiment many others have been done to study transport and mechanical properties of atomic size contacts using an STM[38]. Taking advantage of the unprecedented capability of control that STM has on the displacements, nanometric indentations of the tip in the sample surface can be made to create bridges of variable minimal cross-section[39, 40, 41, 42].

We will review here charge transport through superconducting nanobridges and related structures, and the physical information contained on this transport. Transport regime can be dramatically modified by small changes in the minimal cross-section region, the neck, but the overall nanostructure (nanobridge) remains unmodified when scanning through these regimes in the experiment. At a high level of current, heating and other nonequilibrium effects appear. In atomic size contacts superconductivity and quantum transport phenomena can be studied in a well-controlled manner. Breaking the tip into two parts results into two atomic size nanotips. One of these can be in-situ transported elsewhere and used to make atomic resolution microscopy and spectroscopy over a sample, without change in vacuum or temperature conditions[43]. The application of an external magnetic field confines the condensate around the bridge region creating a nanoscopic superconductor with perfect interface with the normal region, solving in a natural

way the contacting problems [29] associated to this kind of structures. This unique system gives us the possibility to make experiments in a highly controlled situation. Theoretical calculations using Ginzburg-Landau theory and Usadel equations provide a framework to understand the most important aspects of superconductivity in these bridges.

We discuss first how the nanostructures are built and characterized (section II). Then, in section III, we will review theoretical models and experimental results about the transport properties of these systems at zero magnetic field. We discuss separately the three different conduction regimes: tunnel, atomic contact, and low resistance ballistic transport. The same scheme is used to discuss the transport properties in an applied field (section IV). We conclude, in section V, with comments on open questions and future studies which can be addressed with the systems described here.

II. FABRICATION AND CHARACTERIZATION OF THE SUPERCONDUCTING NANOSTRUCTURES

The scanning tunneling (STM) [31] and the atomic force (AFM) [32] microscopes, as well as some related techniques, are versatile tools to penetrate in the nanoworld realm. The STM allows to study the topography and electronic properties of a conducting surface with atomic spatial resolution. In the little more than twenty years elapsed since its invention this technique has become widely used. These instruments can be obtained from commercial suppliers, some of them designed to work at low temperatures. However, home made STM are in use in many laboratories, as they give the required versatility and accuracy for doing specific research. Some home made STMs are well adapted to be mounted in the cryogenic ambiance of ^3He - ^4He dilution and ^3He refrigerators, and to work under magnetic fields[44, 45, 46, 47, 48]. A cylindrically symmetric design is best suited for that. In Fig.1(a) we show a sketch of the STM built and used in the low temperature laboratory of the Universidad Autonoma de Madrid[49], and highlight its original aspects. The coarse approach system, a piston whose controlled movement is produced by piezoelectric stacks, is designed to make, if wanted, strong indentation of the tip in the sample surface. With this system, tip and sample can be approached from distances of several millimeters in-situ at low temperatures. A piezotube with capabilities of vertical displacements, at cryogenic temperatures, in the range of several tenths of microns is used for the fine control and movement. The table on which the sample holder is located is the other important part of this instrument[49]. At low temperatures it can be moved in the x-y plane distances in the millimetric range using piezoelectric stacks. This movement is well controlled and reproducible, and allows to access with the tip a wide surface area within the same cooling down run. Therefore, the sample holder can include a composite sample of different materials, which can be studied together (see Fig.1(b)).

The structures that we discuss in this review have been obtained using superconducting materials and the STM as a tool for its fabrication. We call them nanobridges, because the dimensions of the largest ones are a few hundreds of nanometers. The fabrication of large nanobridges works well with ductile metals like Au, Pb, Al and Sn [38, 41, 50, 51] and semimetals, as it is the case of Bi[52]. The first step of the fabrication is to crash, in a controlled manner, a clean tip into a clean substrate, normally both of the same material (see a schematic representation of the process in fig.2). As the tip is pressed against the substrate, both electrodes deform plastically and then bind by cohesive forces, forming a connective neck (fig.2(b)). Retraction of the tip results in the formation of the neck that elongates plastically (fig.2, frames (c) to (e)) and eventually breaks (frame (f)).

Measuring the current, I , flowing through the neck at a fixed bias, usually between 10 mV and 100 mV, as a function of the displacement, z , of the tip relative to the substrate, it is possible to follow the evolution of the neck. These I - z curves are staircase-like and strikingly reproducible when the process is repeated many times[39, 51]. The detailed analysis of the last steps from these experiments, close to the breaking point of the nanobridge, is often represented as conductance histograms[38]. From those it has been possible to extract, for some simple metals, relevant information on quantum transport through atomic size contacts.

It was soon understood that the staircase shape of the I - z curves reflected the sequence of elastic and plastic deformations followed by the nanobridge [53, 54]. Only the minimal cross section, which determines the conductance and the current I at a fixed voltage, is modified. This is a natural result, as the stress is mostly concentrated around the narrowest part of the nanobridge, the neck. The conclusive evidence came from the combined STM-AFM experiments[41, 50, 55], in which the conductance and the forces which develop during the elongation or contraction of the nanobridge were simultaneously measured. The intimate relation between conductance steps and atomic rearrangements was then established definitively. These experiments were made with lead and gold, being the noble metal the material most thoroughly studied. It was even possible to observe how during the elongation of the bridge, gold deforms plastically down to the last atom contact, and chains consisting of several atoms were created[33, 56].

The conductance observed for these gold atomic contacts is quite close to $1G_0$, where $G_0 = 2e^2/h$ is the value of the quantum of conductance[57, 58]. The force involved in the rupture of these one-atom contacts is also well defined, with a value of 1.5 ± 0.1 nN[33, 55]. Transport experiments in several other elements in the superconducting state

(Pb, Al or Nb, and also in Au, made superconducting using the proximity effect), have permitted to establish a clear relationship between the conductance of the last contact and the chemical nature of the atom involved[59, 60, 61]. Along with these experimental achievements there have been important and successful efforts to get a theoretical understanding of this subject. A recent review by Agraït et al.[38] provides a comprehensive vision of this field.

Here we are mainly concerned with the overall shape of the nanobridges created with the STM and, in particular, using superconducting materials. The results shown in fig.3 were the first clear indication that the controlled fabrication of superconducting nanobridges using a STM as a tool and as a probe was possible[39]. In this experiment, made at 4.2K, high purity lead ($T_c = 7.14$ K) was used for tip and sample. The current for a bias of 50mV was measured changing the area of the contact. Both quantities, minimal cross section and current can be related using the simple Sharvin formula[62]:

$$G_S = \frac{2e^2}{h} \frac{k_F a^2}{2} \quad (1)$$

where $G_S = dI/dV$ is the conductance, a is the radius of the contact, k_F is the Fermi wave vector, h is Planck's constant and e is the electron charge. This expression is strictly valid for ballistic transport (i.e., electronic mean free path $\ell \gg a$) [38]. Assuming that deformations are confined to a small region of volume around the narrowest cross section, and that the neck is parabolic, the evolution of its shape can be obtained from the measured I-z curves (Fig.3). Large nanobridges could be obtained with the procedure schematically represented in fig.4(a). Following a strong indentation the tip is retracted while moving back and forth with a smaller amplitude without breaking the contact. Then a reproducible and regular structure in the current vs tip displacement curves develops.

Untiedt et al. [51] developed a slab model suggested by the results of combined STM-AFM experiments. When the conductance is rather constant, the force varies linearly, while the abrupt jumps in conductance are correlated to abrupt force relaxations. Between the relaxations deformation is elastic so that no energy is dissipated. The nanobridge is modelled as a constriction with cylindrical geometry, consisting of slabs of different radii and thickness, symmetrical with respect to its minimal cross section. The elastic properties of the nanobridge, e.g., the Young's modulus E and Poisson's ratio μ are considered identical to the bulk values. The basic assumption for this model is that only the narrowest part of the nanobridge, the neck, deforms plastically. This assumption could break down for temperatures larger than about 50% of the melting temperature, for which diffusion will be important[51, 63], but it is valid at the temperatures of interest for this review, where atomic mobility is negligible. The slab model provides a good description of the shape and dimensions of the scanned feature, left onto the surface of the sample after breaking a fabricated nanobridge. The atomic sharpness of the tips obtained using this method, permits to obtain images with atomic resolution [43]. A composite sample like the one shown in fig.1(b) was used. After preparing an atomically sharp Pb tip on the lead surface, the sample holder is moved so that the NbSe₂ single crystal surface could be reached and scanned by the tip.

Large amplitude phonon peaks were observed in point contact spectroscopy experiments in long nanobridges with I-z curves showing prominent and repetitive stepped structure[51]. This observation was interpreted as an indication of crystallinity due to "mechanical annealing" of the defects by repeated plastic deformation.

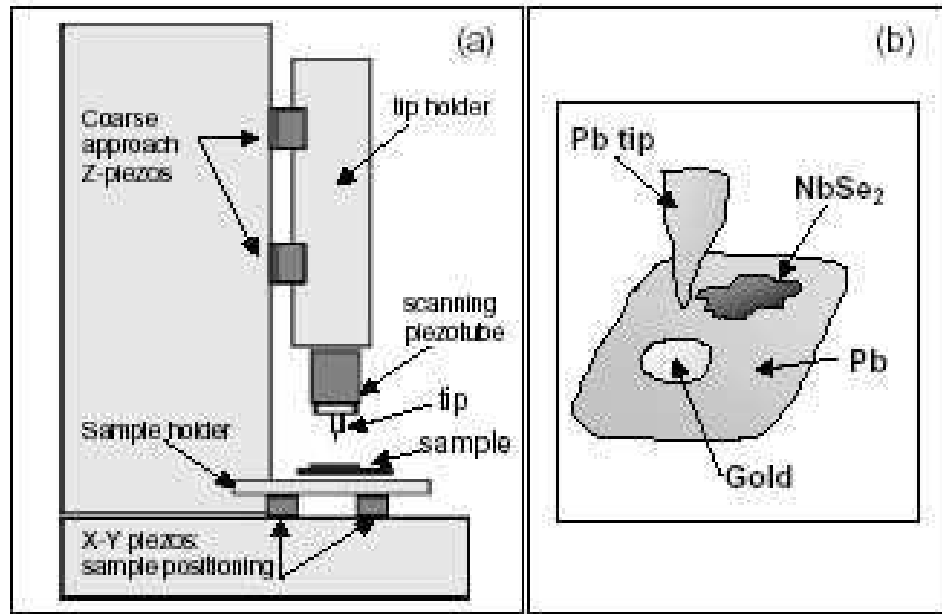


FIG. 1: Scheme of the STM unit (a) and its composite sample holder (b) used in the low temperature laboratory of the Universidad Autonoma de Madrid.

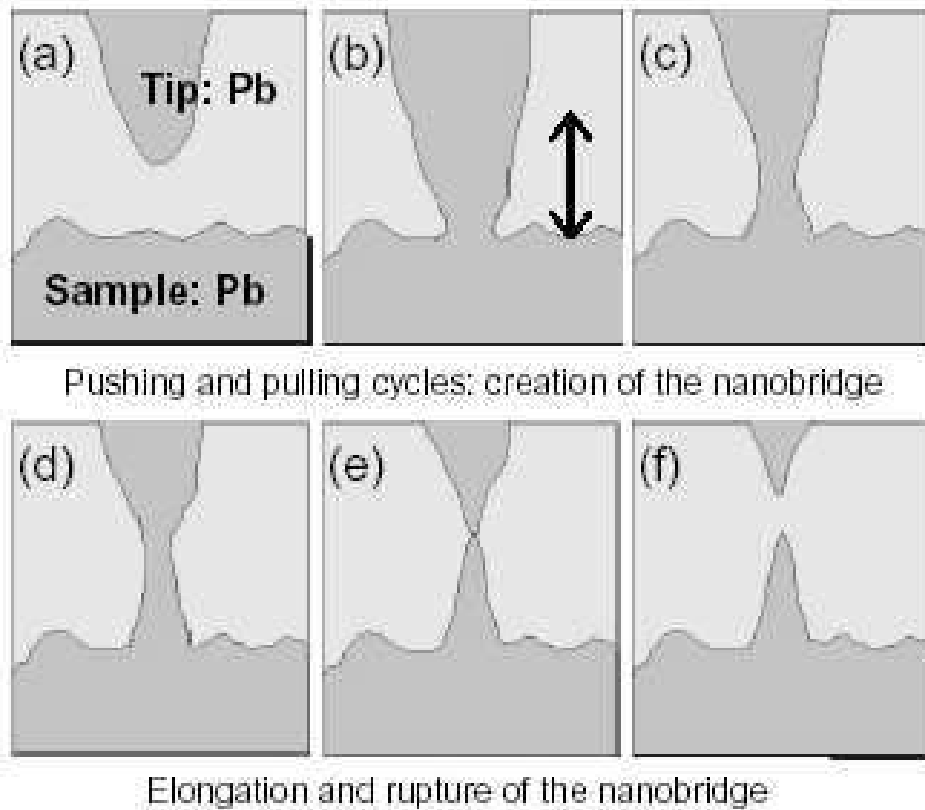


FIG. 2: Sketch of the nanobridge fabrication process. Frames (a) to (f) illustrate different stages of the process: (a) Tip and sample in tunneling regime; (b) The tip is pressed against the substrate, both electrodes deform plastically and form a connective neck; (c) to (e) Indentation-retraction cycles produce a plastic elongation of the neck; (f) the rupture of the nanobridge takes place.

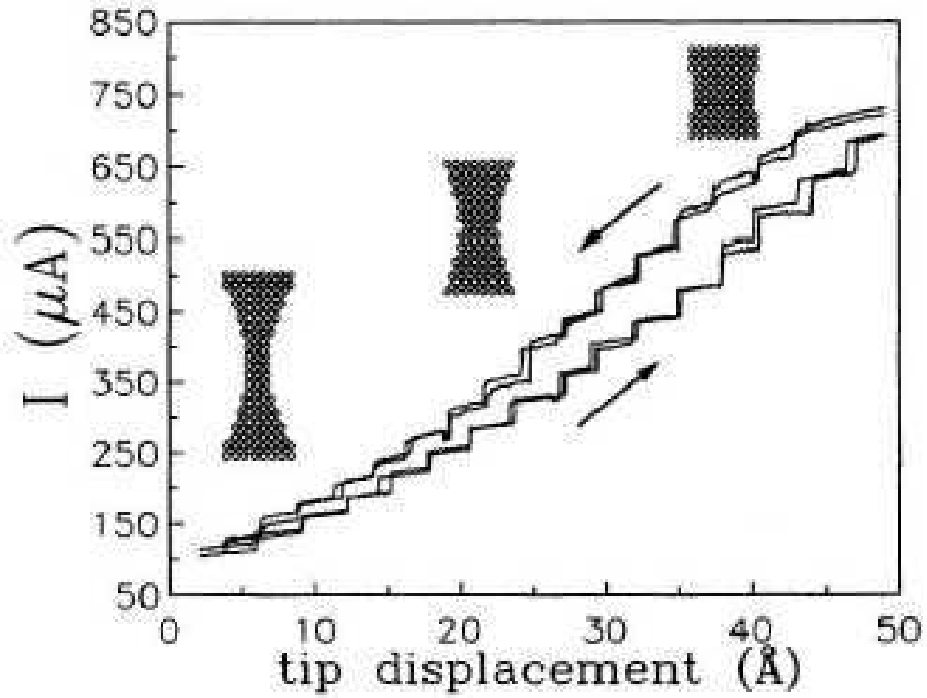


FIG. 3: Experiments made at 4.2 K, using Pb tip and sample, from Ref.[39]. The current for a bias of 50mV was measured changing the area of the contact. A reproducible and regular structure in the current vs tip displacement curves develops. Remarkably, this high reproducibility is obtained in a process involving plastic deformations. The estimated shapes at different stages of the nanobridge along the I-z curves are sketched.

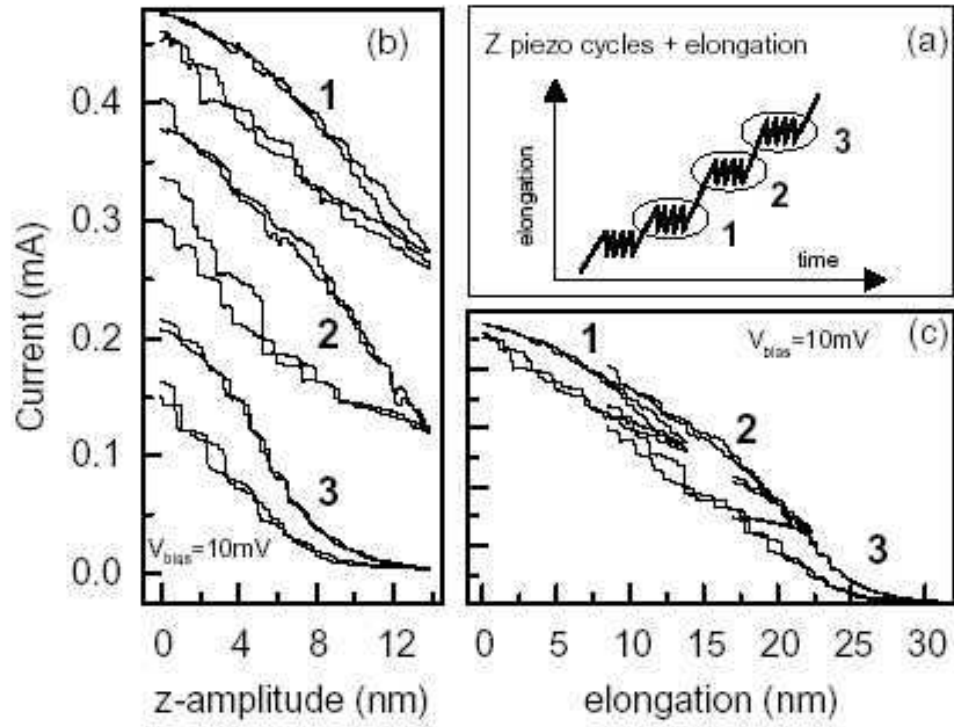


FIG. 4: (a) Schematic indication of the time evolution of the process of elongation of the nanobridge. (b) I-z curves as recorded in a real nanobridge fabrication. Each group of curves (1,2 and 3) correspond to a different stage of the elongation of the nanobridge, i.e., a different neck. These curves can be arranged in order to account for the total elongation of the nanobridge (c). (Data from [64])

III. TRANSPORT REGIMES IN SUPERCONDUCTING NANOSTRUCTURES AT ZERO MAGNETIC FIELD

A. Theory

The current flowing through a tunnel junction (see ref.[65] for a general review on tunneling spectroscopy) is given by the convolution of the density of states (DOS) of both electrodes:

$$I = \frac{G_N}{e} \int_{-\infty}^{\infty} N_1(E)N_2(E) [f(E) - f(E + eV)] dE \quad (2)$$

where N_1 and N_2 are the normalized density of states and G_N is the normal-state conductance of the junction.

For BCS superconducting electrodes, the density of states takes the form[9], $N(E) = Re [E/\sqrt{E^2 - \Delta^2}]$, being Δ the superconducting gap. If tunnelling is performed between two identical superconductors, at zero temperature no current can flow for voltages $V < 2\Delta/e$. At finite temperatures, due to thermal excitations, states above the Fermi level can be populated and those below depopulated, allowing finite quasiparticle current flow at voltages smaller than $2\Delta/e$.

In tunnel junctions where the barrier is sufficiently low, multiple scattering of Cooper pairs leads to a finite conductance below the superconducting gap. In these processes, generically called Andreev reflection[66], an electron is reflected as a hole at the junction, leading to the transmission of a Cooper pair[67, 68, 69, 70, 71]. Subgap Andreev reflection takes place both in normal-superconductor junctions and in superconductor-superconductor junctions. A quantitative analysis of these processes in normal-superconductor (N-S) junctions, was made in ref.[72], and later extended to superconductor-superconductor junctions[73], where the junction was described as two superconductor-normal junctions in series. A complete determination of the transport properties of a superconductor-superconductor junction at finite voltages requires to take into account not only the d.c. current, but also the higher harmonics. A detailed analysis of the time dependent current flowing under an arbitrary applied voltage, taking into account all multiple Andreev reflections (MAR), for a single channel through the junction, was done in ref.[74] and in ref.[75]. At large voltages $V \gg 2\Delta/e$, I-V curves are linear, with a slope given by the normal state conductance, but do not extrapolate to zero. The excess current[76] is defined by

$$I_{exc} = \lim_{V \rightarrow \infty} [I(V) - I_n(V)] \quad (3)$$

with I_n the current in the normal state. At low voltages $V \leq 2\Delta/e$, the I-V curves are strongly non-linear, showing inflections at $eV = 2\Delta/n$. These features, known as Subharmonic Gap Structure (SGS), are a consequence of the multiple Andreev reflections. They can be modified by the internal structure of the junction, or when the transmission coefficient has a significant energy dependence[77].

The non-linearity of the $I - V$ curves has been used to discuss the contribution from different channels in junctions of atomic dimensions[59, 60]. The current in a superconducting-superconducting constriction can be written as the sum of the contribution of N channels in parallel $I = \sum_{n=1}^N i(V, T_n)$ [78]. The current carried by each channel is the corresponding to a one dimensional superconducting constriction with transmission T_n . In the normal state, the total current depends only on the total conductance, independently of the transmission of the individual channels which contribute to it. This is not the case in the superconducting state. In an m -th Andreev reflection process the barrier is transversed $m + 1$ times. The probability that this process occurs scales as T_n^{m+1} . Hence, the total current I strongly depends on the set of individual transmission coefficients.

The current through a superconductor-superconductor (S-S) junction shows other features due to the phase rigidity of the condensate. The most striking manifestation of this property is the Josephson effect[10, 79, 80]. A current below a certain value, I_c , can flow between two superconductors at zero voltage. Following Ambegaokar and Baratoff[81], the critical current, I_c , of a tunnel junction between BCS superconductors can be written as $I_c \approx (\pi G_N \Delta)/(2e)$. This analysis was later extended to other types of junctions[82]. The value of the critical current I_c for a short and narrow constriction was calculated by Kulik and Omel'yanchuk[83] in the case of a point contact much wider than the Fermi wavelength, when the quantization of the momentum can be neglected. Its value for a quantum point contact with a small number of conducting channels was calculated by Beenakker and van Houten[84, 85]. The observation of Josephson current is affected by the balance between the thermal energy, $k_B T$, and the Josephson coupling energy[81], given by

$$E_J = \frac{\Delta R_Q}{2R_N} \quad (4)$$

where R_N is the normal state resistance and $R_Q = h/4e^2 = 6.45k\Omega$. For resistances such that the Josephson coupling energy is comparable to the thermal energy, the superconducting phase dynamics is dominated by thermal fluctuations, making the Josephson current to appear as a peak centered at small finite voltage. In this case the phase motion can be viewed as diffusive. The I-V characteristics of such a junction have been calculated by several authors [86, 87, 88, 89, 90] using the washboard potential model[91].

B. Experiment

The method described in section 2 has been used (see ref.[92] and references therein) to create superconducting tips made of lead and aluminum, with transition temperatures of 7.2K and 1.2K respectively. We will review now the different transport regimes (tunneling, atomic contact and weak-link) accesible through the fabrication and rupture of a superconducting nanobridge. Along this process it is possible to follow in detail the evolution of the I-V characteristics in a wide range of conductance. Fig.5 shows the typical evolution of the conductance spectra, dI/dV vs V , as the junction resistance is varied from vacuum tunnelling regime, $10M\Omega$, to a point contact regime with 100Ω . These STS measurements were done at 1.8 K using tip and sample made of lead.

1. Tunnelling regime

Many spectroscopic experiments made with STM on superconductors have shown I-V curves with notable differences with respect to the expected behavior for a BCS superconductor. It was suggested that the high density of current through the atomic size constrictions could break Cooper pairs, inducing a smearing in the spectroscopic curves[93]. However, it appears that this does not influence the sharpness of the obtained spectra, as emphasized in [47, 92, 94, 95]. Criteria to test the effective resolution of the STM experimental setup have been discussed in refs. [92, 95], based on measurements on aluminum in $^3\text{He}/^4\text{He}$ dilution refrigerators.

Aluminum is considered in many aspects the archetypical weak coupling BCS superconductor, with a well defined value of the superconducting gap. Ideal I-V curves in the S-S tunnelling regime at very low temperature present the well known features of zero current up to the gap edge at 2Δ , where there is a jump to non-zero current[65, 96]. This appears in the tunneling conductance curves (dI/dV vs V) as a divergence at energy 2Δ , present at all temperatures, which is the sharpest feature that can be observed in tunnelling spectroscopy measurements in superconductors. Therefore, the measurement of the current in the tunnelling regime is a direct test of the energy resolution of the experimental set-up. This energy resolution can be introduced in the calculus of the curves as a narrow gaussian distribution, which simulates the noise in the voltage source, and has a halfwidth in energy of σ [92].

Dynes et al.[97] introduced a phenomenological broadening parameter, Γ , into the BCS density of states to account for the broadening of the gap edges in the spectra of dilute bismuth alloys in lead, as due to finite lifetime effects of the quasiparticles. This lifetime broadening model has been applied routinely to situations in which the main source of smearing or broadening of the spectra is of experimental origin. Fig.6 presents an experimental Al-Al tunneling conductance curve measured in a dilution refrigerator, and the corresponding fitting[92]. The calculated curve was obtained with the parameters $\Delta = 175\mu\text{eV}$, $T = 70\text{mK}$ (base temperature of the system) and energy halfwidth $\sigma = 15\mu\text{eV}$. At non-zero temperature the current expected for these junctions at subgap energies is not zero, due to the thermal broadening of the Fermi edge. However, at low temperatures, this current disappears exponentially and it is hardly detectable. Within an experimental resolution in current of 1 pA, the same curve is obtained up to 250mK .

Tunneling experiments using superconducting tips obtained from lead nanobridges fabricated with the STM have been reported[43, 92]. Lead is a strong coupling superconductor, and it was found since early tunnelling experiments[98, 99, 100] that its gap value is not constant over the Fermi surface. Recent results give new support to this scenario[101]. The tunnelling curves

obtained at 0.3K (fig.7(a)) present coherence peaks with a finite width, shown in detail in fig.7(b), larger than the one expected considering only the resolution in energy. This additional width is a consequence of the gaps distribution in lead. The conductance curves are flat bottomed at a zero value of the conductance inside the gap region, indicating the absence of a relevant finite lifetime source. Therefore, the experimental spectra were simulated by means of a gaussian distribution of gap values, as well as a similar distribution accounting for the energy resolution of the spectroscopic system. To fit the experimental data for lead, the temperature (0.3K) and energy resolution ($\sigma = 20\mu\text{eV}$) were kept fixed, leaving the superconducting gap, Δ , and the halfwidth of the distribution of values of the superconducting gap, δ , as free parameters, obtaining $\Delta = 1.35\text{meV}$ and $\delta = 25\mu\text{eV}$. A detailed discussion of this analysis can be found in Refs.[43] and [92].

As lead is a strong-coupling superconductor, the features due to phonon modes are observed in the tunnelling conductance curves (fig.7(a)). According to the well-known properties of strong-coupling superconductors [102, 103], a peak in the effective phonon spectrum gives a peak in the voltage derivative of the conductance located at $\Delta_0 + \omega_{L,T}$, being $\omega_{L,T}$ the energies corresponding to the phonon modes. No significant difference neither in the value of the superconducting gap nor in the phonon modes ($\omega_T = 4.4\text{meV}$ and $\omega_L = 8.6\text{meV}$) with respect to planar junction experiments is found within the experimental resolution. The progressive fading out of phonon features in the S-S tunnelling conductance curves, as both electrodes are approached towards contact was discussed by Rodrigo et al. [104], being a consequence of the mixing of spectroscopic information from different energies close to Fermi level as multiple Andreev reflection processes become more important to the total conduction.

Quasiparticle tunnelling is not the only contribution to the total current. It is also possible to observe tunnelling of Cooper pairs, the Josephson effect. As noted in refs.[45, 105, 106, 107, 108], the measurement of the Josephson effect in atomic size and high resistance vacuum junctions is a true challenge. In a typical tunneling experiment, with normal-state resistances in the $\text{M}\Omega$ range, and not very low temperatures, the thermal energy $k_B T$ is higher than the Josephson coupling energy E_J (eq. 4). For Pb junctions with a normal-state resistance of $1\text{M}\Omega$, both energies are similar at 50 mK. For thermal energies bigger than, but comparable, to the Josephson binding energy, pair tunnelling would be observed, but the pair current will be dissipative, i.e. with the voltage drop proportional to the rate of thermally induced phase slips across the junction [105, 106]. Experiments on ultrasmall Josephson junctions have shown that the Ambegaokar-Baratoff critical current can be reached at low temperature, if the junction is placed in an appropriate controlled electromagnetic environment[109].

By reducing the distance between tip and sample, it is possible to cover a wide range of resistance and temperatures[92, 105, 106, 110], and to get information on different Josephson regimes by changing in a controlled way the ratio between thermal and Josephson binding energies. The increase of the Josephson current as the tunnel resistance is decreased is shown in the inset of Fig.8(a). This effect appears as an increasing peak at zero bias in the conductance curves, observed in the lower curves of Fig.5, which are normalized and blown up in Fig.8(b).

It is important to remark that only the precise determination of the limits in spectroscopic resolution permits to extract relevant information, as the one about the gap distribution in lead, from local tunneling experiments. Recently there have been several reports on new superconducting materials which indicate that a single gap in the Fermi surface is not the more frequent case[92, 95, 111, 112, 113]. Multiband superconductivity and gap anisotropy seem to be more ubiquitous than previously thought. These observations enhance the importance of precise local tunnel measurements to shed light on a variety of open problems.

The STM superconducting tip resulting from the rupture of a nanobridge, in situ at low temperatures, has been used recently[43, 92] to obtain spectroscopic information and topographic images with atomic resolution on other samples. This was possible by using sample holders like the one described in section 2. Other simultaneous STM/STS experiments using superconducting tips were reported in the past. A Nb tip, previously cleaned at low temperature by field emission, was used by the authors of ref.[45] to perform STS on a NbSe_2 sample, whose surface was imaged with atomic resolution. A different approach is described in ref.[114], where a controlled Pb/Ag proximity bilayer was deposited onto precut Pt/Ir tips to obtain STM superconducting tips suitable for STM/STS experiments. Finally, already in 1994, a surface of lead was scanned at 4.2K using a tip of the same element resulting from the rupture of a nanobridge, and spectroscopic measurements at different conductance regimes were performed[115].

2. Atomic size contact regime

As the two parts of the nanobridge are approached, the transmission probability through the barrier increases, and MAR lead to SGS at voltages $V \leq 2\Delta/e$, and to an excess current at large voltages. The appearance of SGS can be seen in fig. 8, both in the current in the inset in (a) and in the normalized conductance in (b). These effects are observed in the curves in figs.5 and 8. Fig.8(a) presents the normalized $I - V$ curves ($I \times R_N$ vs V) corresponding to all the measured range of resistances showing the transition towards contact between tip and sample, and the development of SGS features and the excess current. The SGS features at $V = 2\Delta/ne$ ($n = 1, 2, 3$ and 4) which start to develop in tunneling regime, are finally clearly seen in contact regime (see fig.5). Peaks with high n are enhanced at higher conductance (higher transparency of the barrier) as the probability of multiple Andreev reflections of high order increases.

At present, single atom contacts can be achieved as a routine procedure. The non linear I-V curves of these contacts can be fitted to a sum of contributions from the different quantum channels[59, 60]. The number of conducting channels and their transmission are taken as fitting parameters. The number of channels per atom depends on the chemical element. The individual transmission set changes for different contacts, as shown in fig. 16(a). Only three channels are needed to fit these kind of curves corresponding to Pb contacts [43, 60, 116]. This is taken as an indication that there is a single atom contact between the nanostructures.

Josephson current has been measured in aluminum atomic point contacts containing a small number of well characterized conduction channels[117]. These contacts were made using microfabricated break junctions. The authors found that the value of the supercurrent is related to the dissipative branch of the IV characteristics, like in usual macroscopic Josephson junctions, although in the latter the contribution of the different channels cannot be disentangled. This fact strongly supports the idea of the supercurrent being carried by Andreev bound states and show that the concepts of mesoscopic superconductivity can be applied down to the level of single atom contacts.

3. Weak link regime

When a large point contact is formed between the two parts of the nanobridge, an interesting phenomenology is found in the spectroscopic curves at zero field. As the voltage increased, the system jumps out of the Josephson branch and shows the previously discussed multiple Andreev reflections. Due to the strong current density the temperature raises locally around the contact. The gap decreases and at high voltages the excess current is lost[110, 118]. It vanishes completely when the system reaches locally the critical temperature. This phenomenon appears in the conductance curves as a bump after the SGS, and a recovery of its normal state value when the critical temperature is reached. Heating effects can be controlled in-situ by changing the form of the neck. Long and narrow bridges will show large overheating effects, whereas short and wide bridges are easily thermalised and much larger voltages have to be applied to observe overheating. Local overheating is also commonly observed in classical point contacts [119, 120, 121], although in that case it is not possible to control its magnitude. Fig. 9 shows a typical example of conductance curves corresponding to two different nanobridges with the same normal resistance, 500Ω , equivalent to a minimal cross section of about 20 atoms. The geometry of the bridges can be checked through the evolution of the $I-Z$ curves. Clear heating effects appear in the curve obtained for the long and narrow bridge (curves B) as compared to the situation of a wide bridge (curves A): the SGS peaks move towards lower voltage due to the decrease of the gap value and there is a decrease of conductance, indicative of the loss of the excess current. Finally the conductance recovers its normal state value as the local temperature rises above T_c . These effects are not present in curve A.

Initial works on lead nanobridges fabricated with a STM [110] reported on the above mentioned heating effects, as well as on the crossover between the Ambegaokar-Baratoff (tunneling) and Kulik-Omel'yanchuk (weak-link) limits for the transport of Cooper pairs. Fig.8(a) illustrates the difference in the normalized critical current (i.e. critical voltage) between the tunneling regime (curves A and inset) and the large point contact or weak-link regime (curves C).

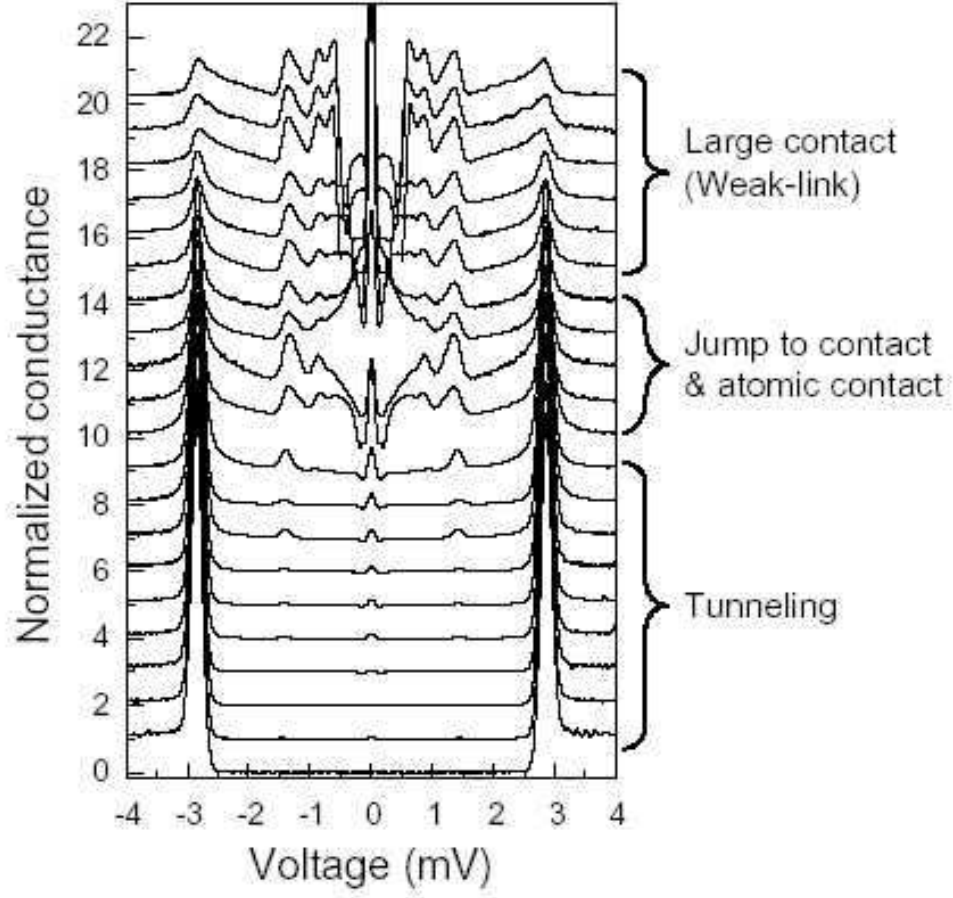


FIG. 5: Evolution of the conduction spectra along the different stages of the creation of a Pb nanostructure (nanobridge). For a given nanostructure, it covers resistances from 100Ω (large point contact) up to $10M\Omega$ (vacuum tunneling). Atomic contact takes place for resistances about $10k\Omega$. Measurement performed at 1.8K. Data from Ref. [64] .

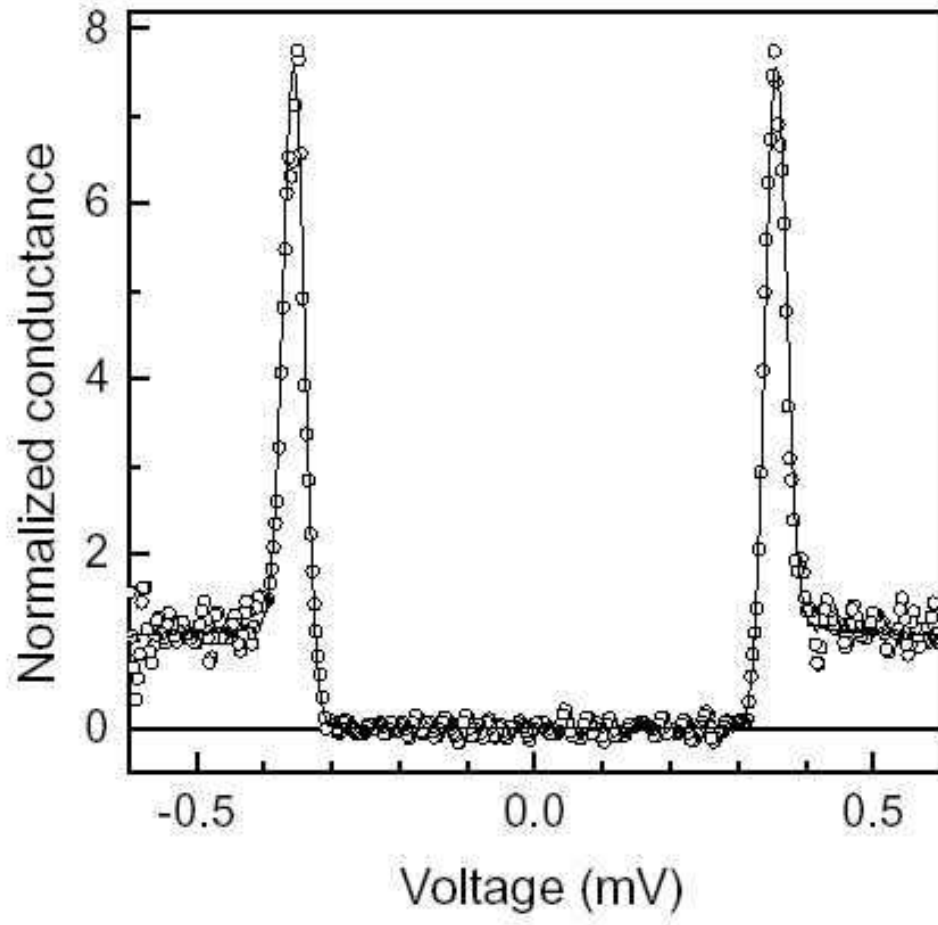


FIG. 6: Al-Al tunnelling conductance curve obtained at 70 mK and its corresponding fitting. Data taken from [92].

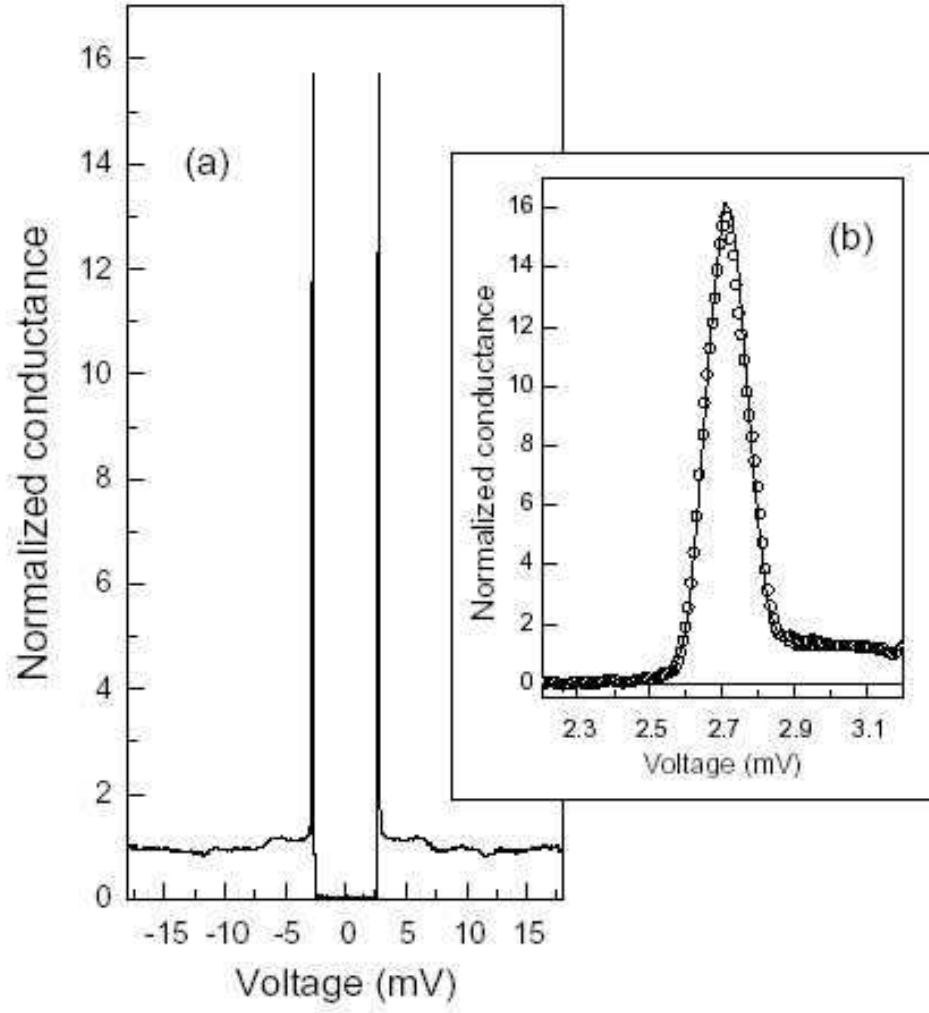


FIG. 7: (a) Tunnelling conductance curve obtained in a ^3He cryostat at 0.3K with tip and sample of Pb ($R_N = 1M\Omega$). (b) Zoom of the gap edge. The theoretical conductance (line) has been calculated with the parameters described in the text, in order to reproduce the experimental curve (circles). Data taken from [92].

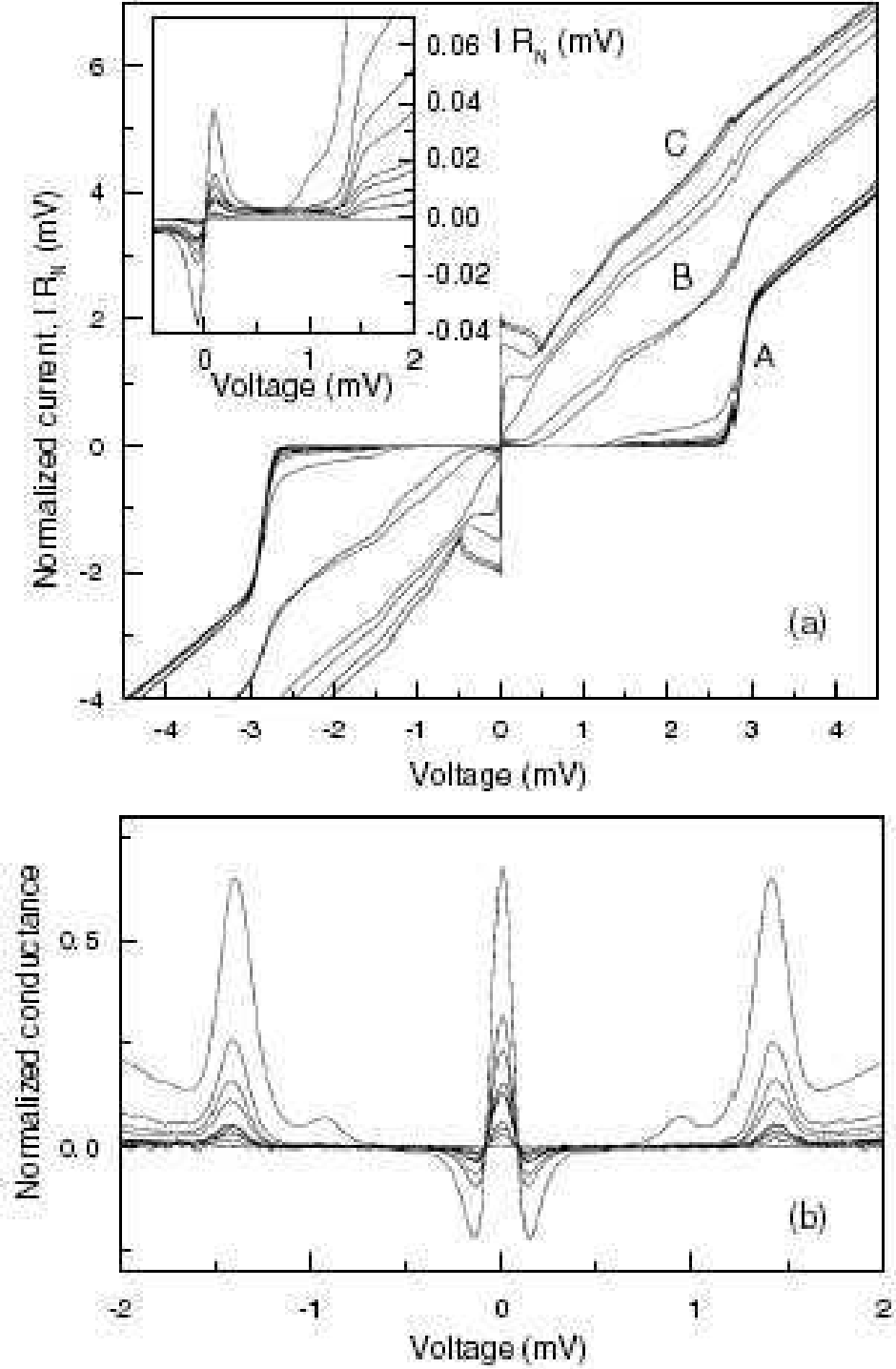


FIG. 8: (a) Normalized $I - V$ curves (IR_N vs V) corresponding to all the measured range of resistances. The different transport regimes can be identified: tunnelling (A), the transition towards atomic contact between tip and sample (B), and large contact regime (C). The SGS features and the excess current develop along the transition from A to C. Inset: blow up of the region close to zero bias for the curves in tunneling regime. (b) Normalized conductance curves corresponding to tunnelling regime. The inset and frame (b) illustrate how the balance between Josephson binding energy and thermal fluctuations affect the observation of Josephson current in tunneling regime. (Data from ref.[64], see also ref.[92])

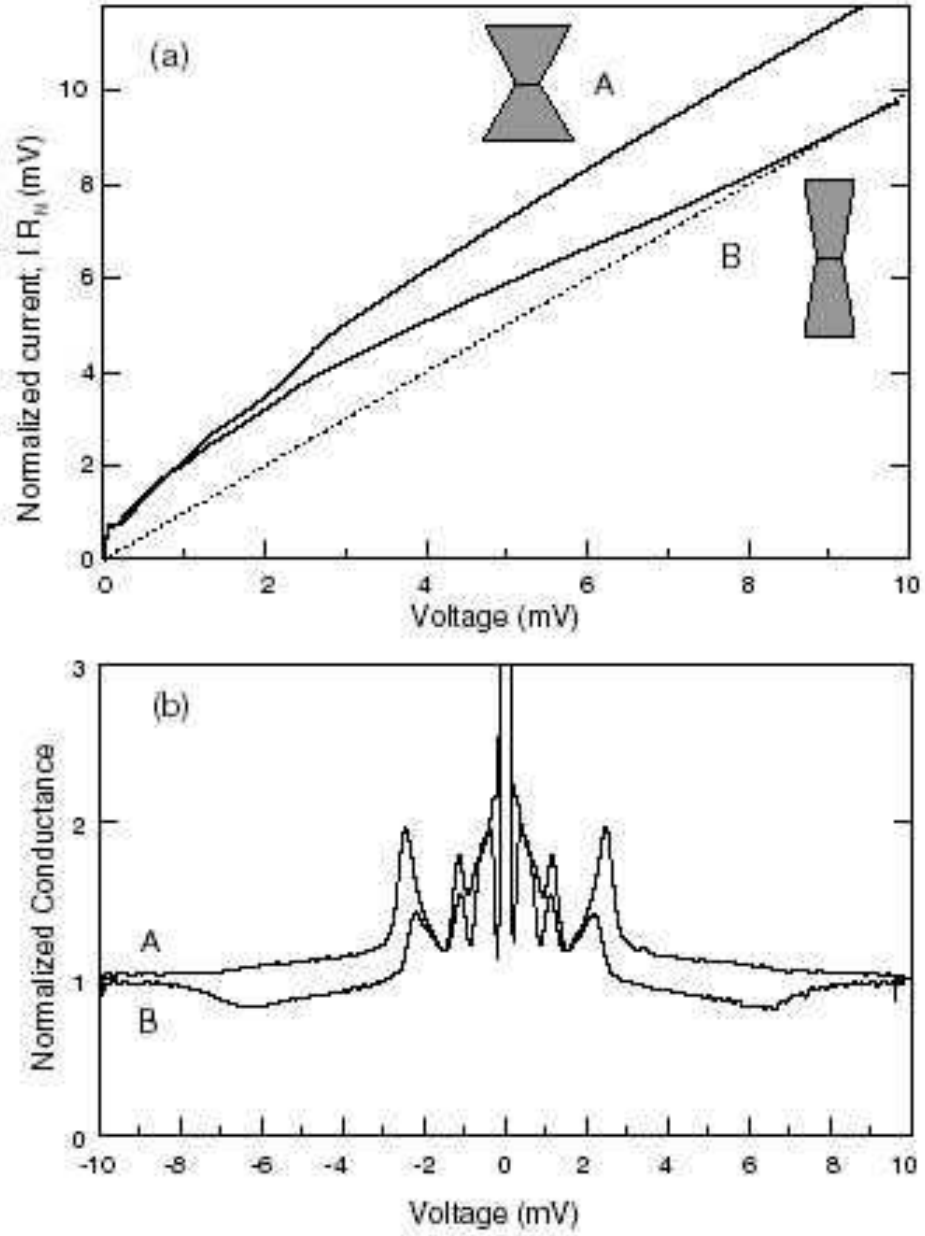


FIG. 9: Normalized $I - V$ (a), and conductance (b) curves corresponding to two different nanobridges with the same normal resistance, 500Ω . Clear heating effects appear for the long and narrow bridge (B). The geometries of both nanobridges are sketched. The dotted curve in (a) indicates the normal state situation. (Data from Ref.[64], see also [46])

IV. SUPERCONDUCTING BRIDGES UNDER MAGNETIC FIELDS

A. Theoretical models

As mentioned in the introduction, samples of dimensions smaller than or of the order of the London penetration depth are superconducting at magnetic fields well above the bulk critical field. The reduced dimensionality blocks the creation of Meissner screening currents, and the kinetic energy associated with them does not contribute to the total free energy of the superconducting state. The lateral dimensions of typical superconducting nanobridges are easily of the order of, or smaller than, the London penetration depth λ . In the case of Pb, which is the material most intensively studied, the zero temperature limit of this quantity $\lambda_0 = 32nm$. Therefore, the superconducting properties of the nanobridges strongly depend on its geometry and on the magnetic field. Several theoretical approaches have been used to describe the experiments. All of them are valid for superconductors in the dirty limit, i.e. with a mean free path ℓ smaller than the superconducting coherence length ξ (in Pb, $\xi_0 = 52nm$). This assumption is easily justified by the typical lateral dimensions of the nanobridge, which can be taken as a good measure of the order of magnitude of the relevant mean free path ℓ [51, 122]. The reduction of ℓ does not affect the superconducting properties of isotropic, s-wave superconductors[123].

In uniform two dimensional or one dimensional structures, as thin films or wires, the effect of a parallel magnetic field is well described by the pair-breaking theory, reviewed in Ref.[124], and originally developed to account for the effect of magnetic impurities [125]. Contrary to the simple BCS case, in the presence of a pair-breaking mechanism the order parameter and the gap in the spectrum are not equal, and gapless superconductivity is found close to the critical field. As shown below, a more elaborate treatment, the variable radius pair breaking model (VRPB), is needed to account for the particular geometry of real nanobridges, which are three dimensional cone-like objects[116, 126]. The VRPB model uses Usadel's formalism and gives the temperature and magnetic field dependence of the density of states. It reduces to the pair-breaking description[124] when considering a uniform wire. Alternatively, the Ginzburg-Landau (GL) approach has been used to obtain information about the geometrical distribution of the superconducting condensate in the nanobridge, its eventual vorticity and the dependence of the critical current as a function of field.

1. Usadel approach. VRPB model

The electronic structure of a superconductor can be described in terms of a 2×2 Green's function, which obeys the Gorkov's equations. These equations can be simplified when the interesting scale in the problem being considered is much larger than the Fermi wavelength λ_F [127]. In the quasiclassical approximation, the oscillations of the Green's function, on a scale of λ_F , are averaged[128]. In the dirty limit the Green's function is almost isotropic and an expansion in spherical harmonics keeping only the $L = 0$ term can be made. The Green's functions are obtained from Usadel equations.[129, 130] With these assumptions the Greens's function can be parameterized in terms of two position and energy dependent complex angle variables, $\theta(\vec{r}, E)$ and $\Phi(\vec{r}, E)$ [130, 131, 132]:

$$\hat{g}(\vec{r}, E) \equiv \begin{pmatrix} g & f \\ f^\dagger & g \end{pmatrix} \equiv \begin{pmatrix} \cos[\theta(\vec{r}, E)] & \sin[\theta(\vec{r}, E)]e^{i\Phi(\vec{r}, E)} \\ \sin[\theta(\vec{r}, E)]e^{-i\Phi(\vec{r}, E)} & \cos[\theta(\vec{r}, E)] \end{pmatrix} \quad (5)$$

g being the ordinary propagator, f the anomalous Green's function and f^\dagger its time reverse. Superconductivity is characterized by a non-vanishing f , which gives the probability amplitude for the destruction of a Cooper pair. With this parametrization, the superconducting order parameter $\Delta(\vec{r})$, which has to be determined selfconsistently, and the density of states $N(\vec{r}, E)$ are given by:

$$\begin{aligned} \Delta(\vec{r}) &= N_0 V \int_0^{\omega_D} dE \tanh\left(\frac{E}{K_B T}\right) \text{Im}[\sin \theta(\vec{r}, E)] \\ N(\vec{r}, E) &= N_0 \text{Re}[\cos \theta(\vec{r}, E)] \end{aligned} \quad (6)$$

with N_0 the normal density of states, and ω_D the Debye frequency. If there is no current $\Phi(\vec{r}, E)$ is a constant equal to the phase of the order parameter and we can drop it in the following.

Let us consider an axially symmetric superconductor in a magnetic field H parallel to its axis. The superconductor is assumed to be thin enough to neglect screening due to superconducting currents, and the vector potential \vec{A} is

given by $\vec{A} = \frac{1}{2}Hr\vec{e}_\phi$. Usadel's equation can be written as:

$$\frac{D}{2}\nabla^2\theta + \left[E - \frac{1}{2\tau_{in}}\right]\sin\theta + |\Delta|\cos\theta - \left[\frac{1}{2\tau_{pb}} + 2e^2D|\vec{A}|^2\right]\cos\theta\sin\theta = 0 \quad (7)$$

where τ_{in} and τ_{pb} are the inelastic and pair breaking scattering times[124] and $D = \frac{1}{3}\ell v_F$ the diffusion coefficient. When the superconductor is thinner than the coherence length, the radial dependence of the quantities of interest can be neglected, and \vec{A}^2 replaced by its average $\langle A^2(z) \rangle = H^2 R^2(z)/12$, where z is the distance to $\vec{r} = 0$ along the superconductor, i.e. parallel to H . The pair breaking effect of the magnetic field is the given by:

$$\Gamma_0^H(z) = e^2 D H^2 R^2(z)/6 \quad (8)$$

Note that Γ_0^H becomes strongly position dependent and increases, for a fixed field H , with the square of the radius of the sample $R(z)$.

In uniform wires, where R is constant, the pair-breaking term due to the field is also constant in all the wire and $\nabla\theta = 0$. Neglecting inelastic scattering processes and pair breaking effects other than those due to the applied field, the following equation is obtained:

$$\frac{E}{|\Delta|} = u \left(1 - \frac{\Gamma}{\sqrt{u^2 - 1}}\right) \quad (9)$$

where $\Gamma = \Gamma_0^H/|\Delta|$ and the parameter u is defined by $\cos\theta = \frac{u}{\sqrt{u^2 - 1}}$ and $\sin\theta = \frac{-i}{\sqrt{u^2 - 1}}$. In this way, the description for uniform superconductors with pair breaking effects is recovered[124]. The magnetic field penetrates in the superconducting region, inducing pair breaking effects and reducing the superconducting gap. The density of states, shown in the inset of Fig. 10, remains gapped up to fields very close to the critical one ($H_{gap} \sim 0.9H_c^{wire}$, with $H_c^{wire} \sim (\frac{3}{e^2 D})^{1/2} \frac{1}{R}$).

In cone-like nanobridges $R(z)$ and $\Gamma_0^H(z)$ smoothly increase with the distance z with respect to the center of the structure at a given magnetic field H . The superconducting order parameter will be eventually suppressed at a certain distance, creating an N-S-N structure, in which only the central part of the nanobridge remains in the superconducting state. From eq. (7), the magnetic field, temperature and position dependence of the superconducting order parameter and density of states is obtained by introducing a $R(z)$ function which reproduces the geometry of typical nanobridges. R becomes a simple linear function of z if the nanobridge is modelled by two truncated cones each of length L , with an opening angle α , joined by their vertices and attached to bulk electrodes, as shown in the inset of Fig.11 [116, 126]. Fig.11 shows the superconducting order parameter as a function of the distance for different applied fields and typical α and L . There is a smooth transition to the normal state as the radius of the nanobridge increases. The magnetic field dependence of the density of states at the center of the nanobridge, calculated using the same $R(z)$ as in fig.11, is shown in fig.10. A large amount of low energy excitations, induced by the proximity effect from the normal parts of the nanobridge (fig.11), is found in the whole field range. In fact, the superconducting gap is lost already at fields very close to the bulk H_c (0.08T), which contrasts the case of a uniform wire (inset of fig.10). As shown below, these differences can be addressed experimentally.

2. Ginzburg-Landau approach.

The Ginzburg-Landau (GL) approach [8] has been extensively applied to the study of the distribution of the magnetic field and the superconducting phase in small superconducting systems[16, 17, 133]. A very good account of the geometrical distribution of the order parameter is obtained, although the details of the density of states are more difficult to address. Its applicability is, in principle, restricted to temperatures close to T_c , where it becomes equivalent to Usadel's formalism [134].

The theoretical analysis makes use of the similarities between the Ginzburg-Landau equations for planar superconductors in a magnetic field and the Schrödinger equation for a particle in a field[135]. The predicted magnetic structure is very rich[19, 20], and it has been compared with experiments[18, 136]. Characteristic vortex configurations observed in refs. [18, 136] originate from the competition between the vortex-vortex interaction and the vortex-sample edge interaction [137].

GL equations have been also applied to study the distribution of the superconducting phase in an isolated (non-connected to large electrodes) cone-like geometry[138, 139], which precisely models the nanobridge created in [122]

(see Fig.12). The 3D equations have been solved, relaxing the assumption of an order parameter constant in the radial direction. These results confirm the applicability of the VRPB model. Already at low magnetic fields, it is found that the parts of the nanobridge with larger radius transit to the resistive state. At the highest magnetic fields, the superconducting phase is concentrated near the neck of the bridge, and very interesting, ring-shape areas, indicating states with finite vorticity, appear in a short range of fields and at low temperatures. These calculations have raised the question, not yet addressed in published experiments, of the possible confinement of vortices within the smallest possible superconducting structure. The fundamental properties of these vortex states represent, in our opinion, an interesting field for future studies.

The modification of the critical field of a thin wire by the presence of a current has been also calculated within the GL approach. The critical current, in the absence of the field, is:

$$I_c(T) = \frac{H_c(T)R^2c}{3\sqrt{6}\lambda(T)} \quad (10)$$

In terms of this quantity, the critical field in the presence of a current, and the critical current as function of field can be written as[126]:

$$\begin{aligned} H_c(T, R, I) &= H_{wire}(R, T) \sqrt{1 - \left[\frac{I}{I_c(T)} \right]^{2/3}} \\ I_c(T, R, H) &= I_c(R, T) \left\{ 1 - \left[\frac{H}{H_{wire}(R, T)} \right]^2 \right\}^{3/2} \end{aligned} \quad (11)$$

with

$$H_{wire}(T) = \sqrt{32}H_c \frac{\lambda(T)}{R} \quad (12)$$

An extensive analysis of the functions H_c and I_c can be found in[126]. It is found that a magnetic field above the bulk critical value reduces the critical current. This reduction is more important for wires with larger radius R .

B. Experiments

Previously we have discussed the experimental situation at zero magnetic field in the different conduction regimes, tunnelling, atomic size contact and weak link regimes. Experiments under magnetic fields confirm the applicability of the VRPB and GL models and show up new effects, associated with the presence of a N-S interface near the center of the nanobridge.

1. Tunnelling regime.

The tunnelling conductance in the superconducting state has been measured following the rupture of narrow and symmetric nanobridges of Pb[92, 140, 141]. In these tunnel junctions, superconducting correlations have been observed up to magnetic fields as high as 2T, i.e. at fields 25 times higher than the zero temperature critical field of bulk samples (0.08T). In all cases, a large amount of low energy excitations is observed, which can only be explained taking properly into account the geometry of this structure, as in the VRPB model.

I-V curves calculated with the constant pair breaking model[124] do not reproduce the large current found in the low voltage part of the measured I-V curves, as shown in the inset of Fig.13a. By contrast, the VRPB model, using parameters consistent with the geometry of typical nanobridges, leads to calculated I-V curves, which do indeed follow the experiment, as shown in Fig.13a) and b) for two different samples. Note that the same geometry is used to fit the whole field range. The large amount of current found in this range is the result of the excitations induced by the proximity effect from the parts of the nanobridge with largest radius, which transit to the normal state at smaller fields than the central part of the nanobridge(Fig.11). The destruction of superconducting correlations is a combined effect of the proximity from the perfectly connected normal parts around the superconducting neck, and the pair breaking effect of the magnetic field. These results show, quite unambiguously, that the magnetic field restricts the volume of the superconducting phase to its minimal size.

The features in the density of states corresponding to the phonon structure (see Fig.7) have been followed as a function of the magnetic field in Ref.[140], giving the unique possibility to study the pair formation when, gradually, superconductivity is confined to the smallest length scales. In Fig.14 the variation of the characteristic phonon modes is shown as a function of the magnetic field. To normalize the position in energy of the phonon features, following previous experiments and calculations for thin films in Refs.[142, 143], the phonon frequencies $\omega_{L,T}$ are subtracted from the voltage position of the features corresponding to the transverse and longitudinal phonons $\epsilon_{L,T}$, and divided by twice the zero field superconducting gap $2\Delta_0$. The data (fig.14) follow well the calculations of [143], intended to explain the experiments in thin films [142]. The confinement of the superconducting correlations to its minimal size by increasing the magnetic field occurs without specially marked changes in the way the Cooper pairs are formed. The perfect connection between the smallest superconducting part of the nanobridge and the large bulk in the normal state, is the key element to understand the superconducting state under magnetic fields in these nanostructures.

Somewhat different experiments have been done by transporting one half of the broken nanobridge, i.e. a nanotip (see Fig.2), to a more flat region onto the Pb sample[92]. In that case, the flat region of the sample is in the normal state, while the tip remains superconducting under field, resulting in characteristic N-S tunnelling curves, which can only be satisfactorily explained within the VRPB model. In Fig.15 representative series of data taken as a function of temperature (a) and its corresponding theoretical calculations (b) are shown. Again, these results evidence the strong reduction of the size of the superconducting part under magnetic fields.

2. Atomic size contact regime.

The multiple Andreev reflection pattern has been followed as a function of the magnetic field in many single atom point contacts made in nanobridges with different geometries [116, 126, 141]. The atomic arrangements around the contacting atom are easily changed without destroying the overall shape of the nanobridge, so that a large series of contacts can be studied at a given magnetic field. The subharmonic gap structure (SGS) is gradually smeared out by the magnetic field.

I-V curves made under magnetic fields in some nanobridges have been reproduced using a uniform pair breaking parameter Γ and the typical distribution of conduction channels found in Pb (fig.16). However, the magnetic field dependence of Γ was found to be inconsistent with formula (8), making impossible to give a physical meaning to the values of Γ used within this description[116]. Moreover, subsequent work [126] has found significant discrepancies in situations where the N-S interface moves close to the contact, as e.g. at fields close to the complete destruction of superconductivity. The VRPB model, by contrast, gives an adequate fit to the experiment in every case, as shown in a representative example of curves in Fig.17. The same geometry, compatible with the one determined experimentally, is used for a given nanobridge in the whole magnetic field range[116].

A remarkable conclusion of these experiments is that the magnetic field does not change the essential properties of the atomic size contact, in the sense that the same distribution of conduction channels is needed to fit the experiments. When the field is applied no conduction channel is closed nor a new channel opens[116]. In fact, the flux going through the contact, even at fields of several T, is much too small to produce changes in the electronic transport in the neck or in the orbital structure of the contacting atom.

Other experiments made with the break junction technique in Al also show how atomic size contact curves are smeared by the application of a magnetic field[144]. In those experiments, one contact was followed as a function of the magnetic field to maintain the distribution of channels constant in the whole field sweep. Their results were interpreted using the pair breaking model to account for the influence of the magnetic field. However, superconductivity was lost at the bulk critical field of Al (9.9mT). This technique does not produce nanobridges, so that the region surrounding the contact has the same magnetic response as the bulk, which is in the Meissner state. The magnetic field distribution around the contact should be complex due to demagnetization effects.

The fabrication of a nanobridge around the contact, and the concomitant observation of superconductivity above the bulk critical field, is necessary to get an accurate control over the magnetic response of the system.

3. Weak link regime.

As discussed above (section III.B.3), cone-like structures which are connected through a large contact of several nanometer in radius show considerable local overheating effects(Fig.9). As a consequence, a bump, indicative of the loss of the excess current (formula (3)), appears in the differential conductance. Under magnetic fields, the position of the bump moves to smaller voltages, due to the decrease of the superconducting order parameter.

Interesting situations have been reported in which the conductance shows two bumps whose voltage positions have different magnetic field behaviors. These results have been interpreted as being characteristic of asymmetric

nanobridges, in which each half of the cone-like structure has a different opening angle, and therefore also a different power dissipation rate[145]. The half with a smaller opening angle is more easily heated than the half with a larger opening angle. However, the former has a higher critical field than the latter. Correspondingly, while the position of the feature corresponding to the first loss of the excess current (the side with the smaller opening angle becoming normal) remains almost constant, the voltage at which the second loss takes place (the side with larger opening angle) varies strongly with the applied field. These experiments show that it is possible to obtain relevant information about the nanobridge by a careful analysis of the observed I-V curves in the weak link regime.

On the other hand, in sufficiently long and narrow nanobridges with a symmetric geometry a striking phenomenology has been found with two well defined regimes as a function of the magnetic field[46]. A series of peaks appears in the differential resistance below a magnetic field which corresponds to about half of the field for the complete destruction of superconductivity (0.2 T in Fig.18) [46]. These peaks are located at different voltages, but always well above the superconducting gap, and have been associated to the appearance of resistive centers in the nanobridge, in close analogy to the phase slip centers observed in thin wires[91]. At higher fields (above 0.23T in Fig.18), a new regime sets in. The differential resistance steeply increases with the voltage, and abruptly drops to its normal state value when the local critical temperature is reached. This results in a single sharp peak, instead of the smooth structure observed at zero field, which disappears abruptly at the critical temperature, and is always observed when the N-S interface moves close to the central part of the nanobridge, as for instance near T_c [46, 145]. Therefore, it has been associated to the establishment of a region within the superconducting nanobridge, where a finite voltage drops. This voltage has been attributed to a non-equilibrium situation created by the conversion of normal current into a supercurrent, as expected near N-S interfaces[146]. Several experiments and theoretical calculations have addressed the observation of such non-equilibrium voltages in thin films, nanolithographed structures, or nanoscopic wires [91, 146, 147, 148, 149, 150, 151, 152, 153]. The nanobridges created with the STM have two remarkable differences with respect to those structures. First, the N-S interface is formed in a natural way within the same material, eliminating possible interface problems, which may appear in evaporated structures. Second, nanobridges created by the STM also have much smaller lateral dimensions enhancing the observed non-equilibrium signals.

Finally, we discuss the Josephson effect, which has been treated in the literature in the large-contact regime with more detail than in the tunnelling and single atom atomic size contact regimes. In Ref. [122], the critical current has been followed as a function of the size of the contact. The qualitative trend is explained with the calculations using GL model. In Ref. [145], the form of the I-V curve near zero bias is studied. It is shown that at zero field the zero bias conductance does not diverge, but remains finite between $0.999T_c$ and T_c , an effect typically observed in weak links due to thermal activated phase slip through the barrier[91]. However, this temperature range strongly increases in nanobridges under magnetic fields. In some samples, a finite zero bias conductance has been observed between $0.3T_c$ and T_c . This is a striking result, and it is unclear if it can solely be explained by the modification of the superconducting order parameter in the VRPB model[145].

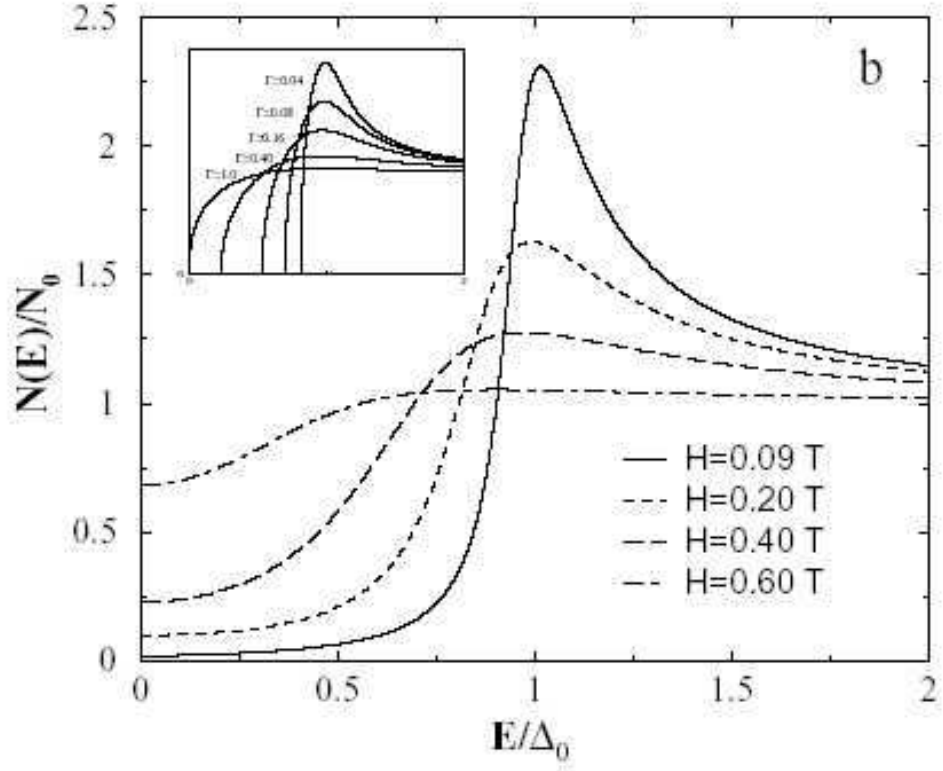


FIG. 10: The density of states at the neck calculated using VRPB model, and corresponding to $L = 850\text{\AA}$, $\alpha = 45^\circ$ (see inset of Fig.11) is shown as a function of the magnetic field. The coherence length is reduced to $\xi = 325\text{\AA}$ to model the changes in ℓ at the nanobridge. In the inset the density of states calculated using a pair breaking model, is represented for different values of Γ . Note the absence of low energy excitations in a large range of Γ , a point which is not reproduced in the experiments, as discussed further on. From [116, 126].

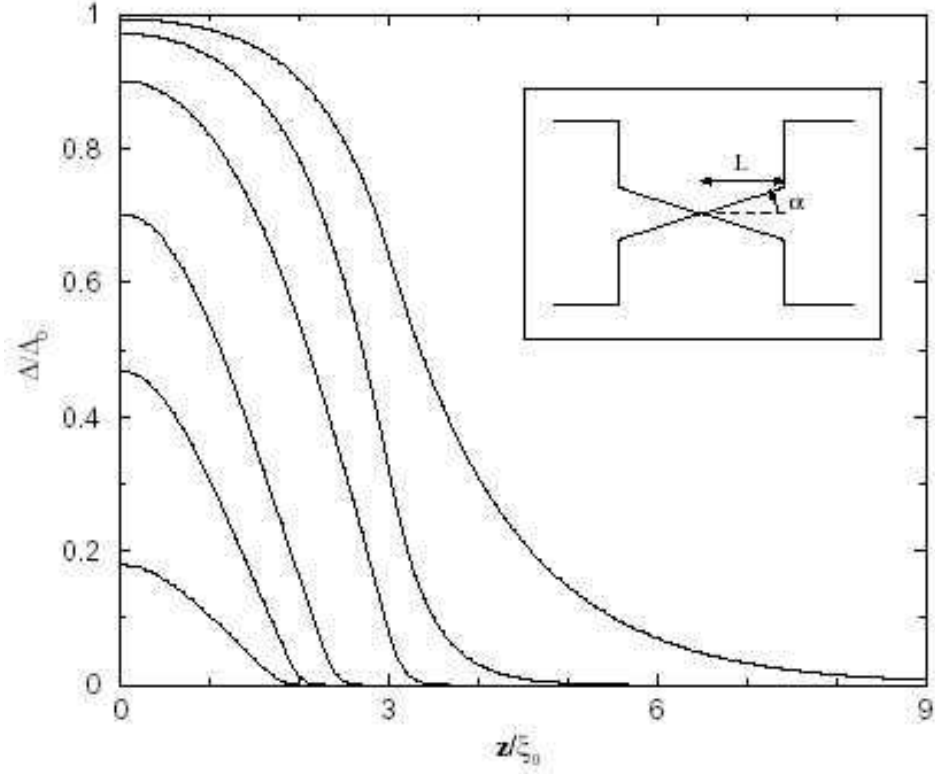


FIG. 11: The inset shows the geometry used in the variable radius description (VRPB). The main figure shows the dependence of the superconducting order parameter, within VRPB, as a function of the distance from the center of the nanobridge, for different applied fields (from top to bottom, 0.09, 0.2, 0.4 and 0.6 T), using the same geometry as in the previous figure. The neck is joined at the electrodes at $z/\xi = 2.6$. From [116, 124]

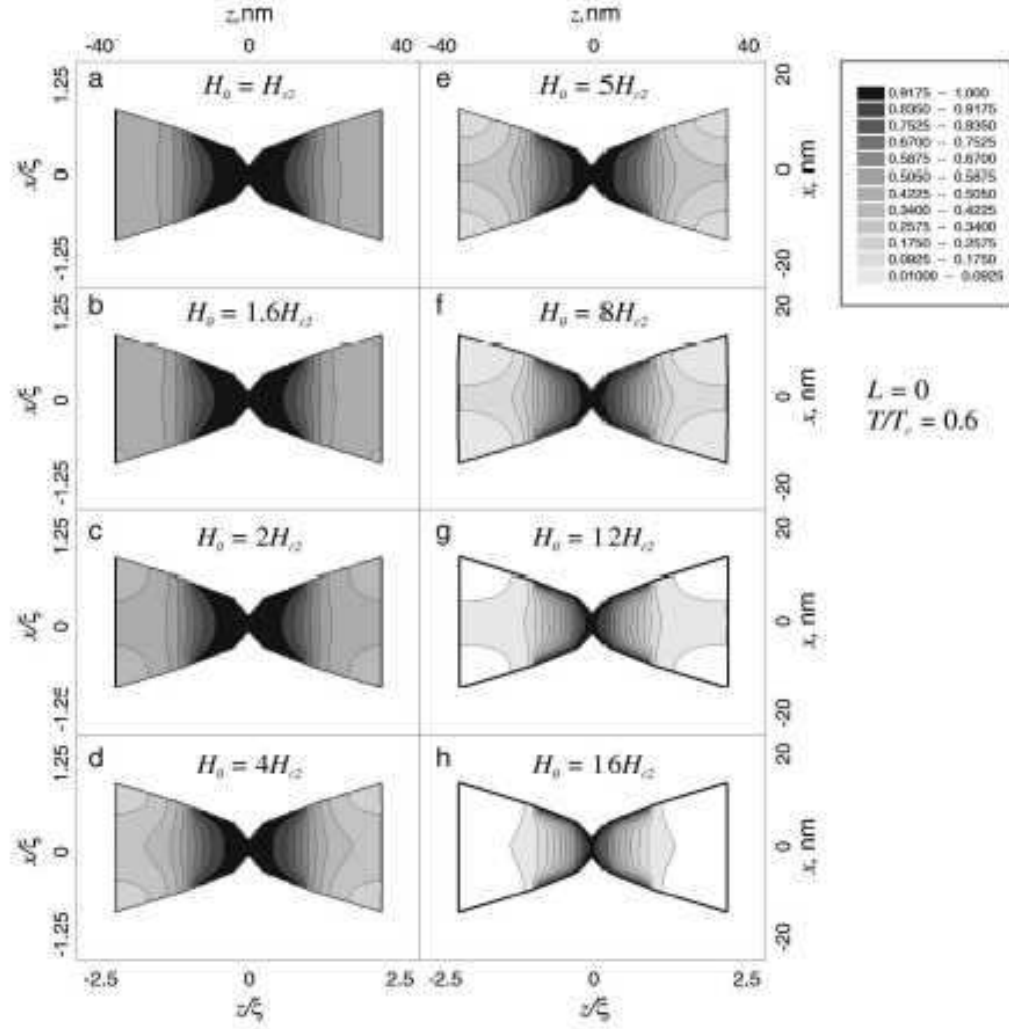


FIG. 12: Distribution of the superconducting order parameter in a nanostructure at different magnetic fields (at $T/T_c=0.6$) (from[138]). Superconductivity survives at the central part of the neck up to fields much higher than the bulk critical one.

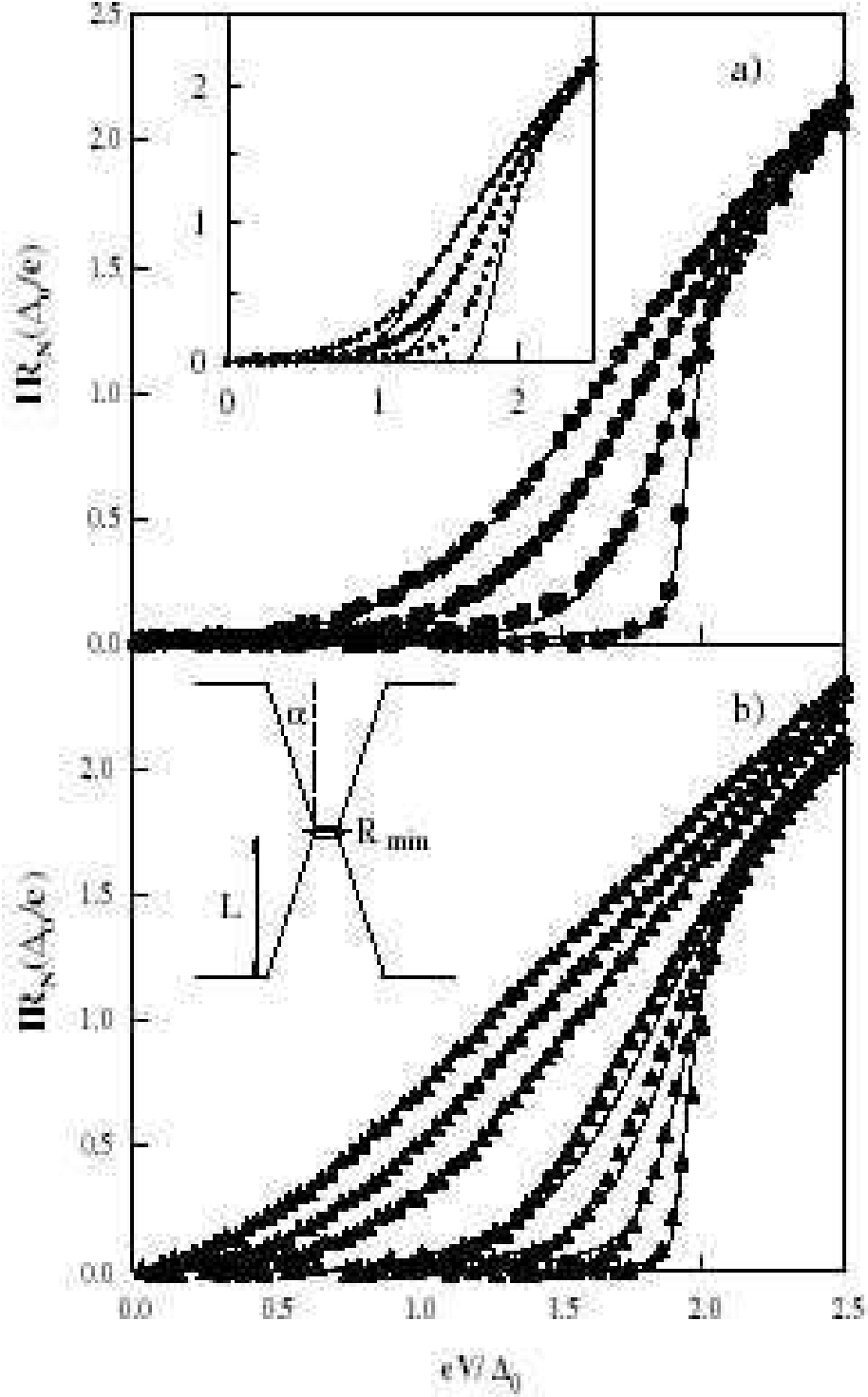


FIG. 13: Current (symbols) as a function of bias voltage at $T = 0.4$ K (a), from bottom to top $H = 0, 0.13, 0.18, 0.23$ T, and $T = 1.5$ K (b) from bottom to top $H = 0, 0.17, 0.34, 0.5, 0.84, 1.01, 1.18$ T, for two characteristic nanobridges with the magnetic field applied parallel to the bridge in (a) and perpendicular in (b). Solid lines correspond to the fittings obtained within a variable radius geometry (VRPB, see inset in b. and fig.11). Inset in a. shows calculations (lines) together with experimental curves (points) using a single pair breaking parameter (inset in fig.10, from bottom to top: $\Gamma_0 = 0.04, 0.13, 0.21$). This model does not reproduce the large measured current at low voltages. From [140].

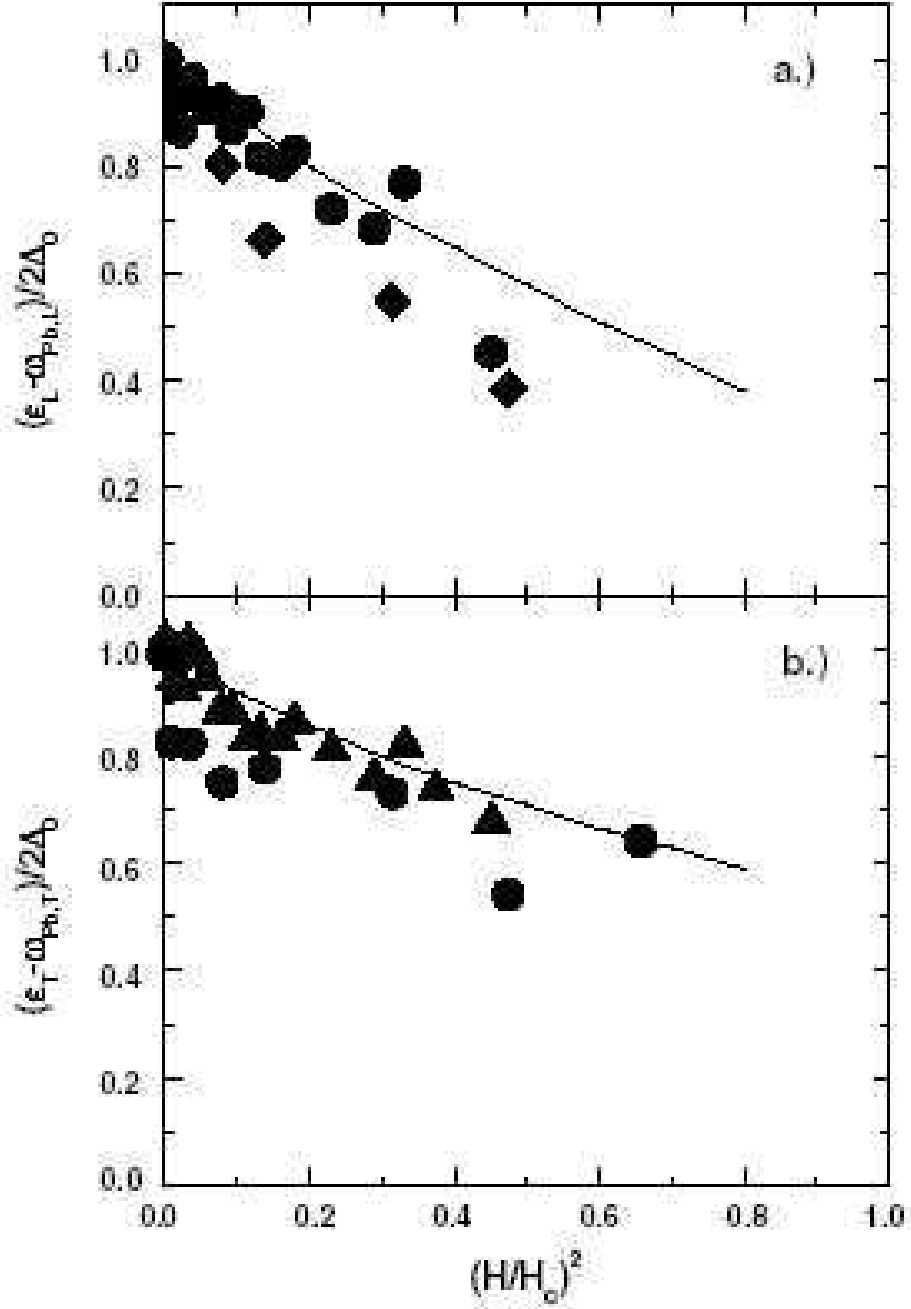


FIG. 14: The strong coupling features corresponding to the longitudinal (a) and transversal (b) phonon modes ($\omega_{L,T}$) is shown as a function of the magnetic field. The data are extracted directly from the position of the corresponding features in the tunneling density of states ($\epsilon_{L,T}$), and plotted normalized to the superconducting gap at each field. The theory developed by [143] (lines) explains the data. From [140].

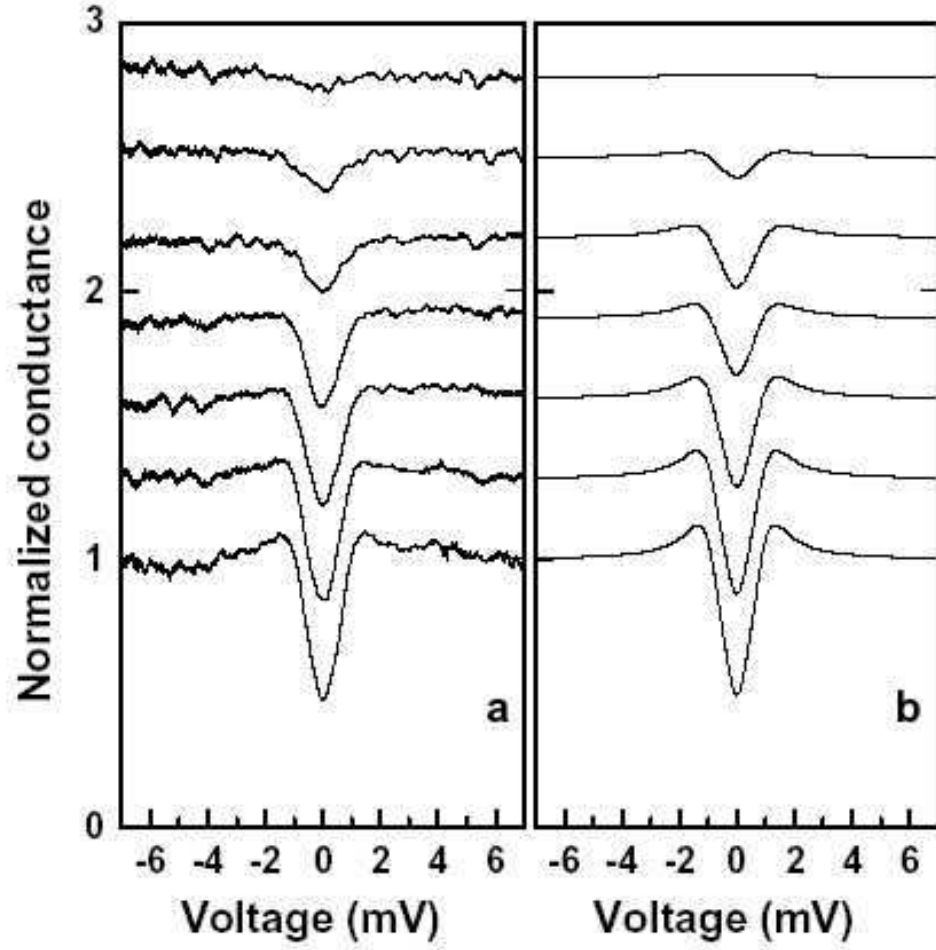


FIG. 15: After the creation of the nanostructure, if the tip is transported to a region of the sample which is flat, curves characteristic of N-S junctions are obtained, with the superconducting density of states showing a large amount of low energy excitations (experiment, a), explained within the variable geometry model of Ref.[116] (calculated curves in b). From bottom to top, $T = 1.0, 1.5, 2.0, 2.5, 3.0, 3.5, 4.0K$

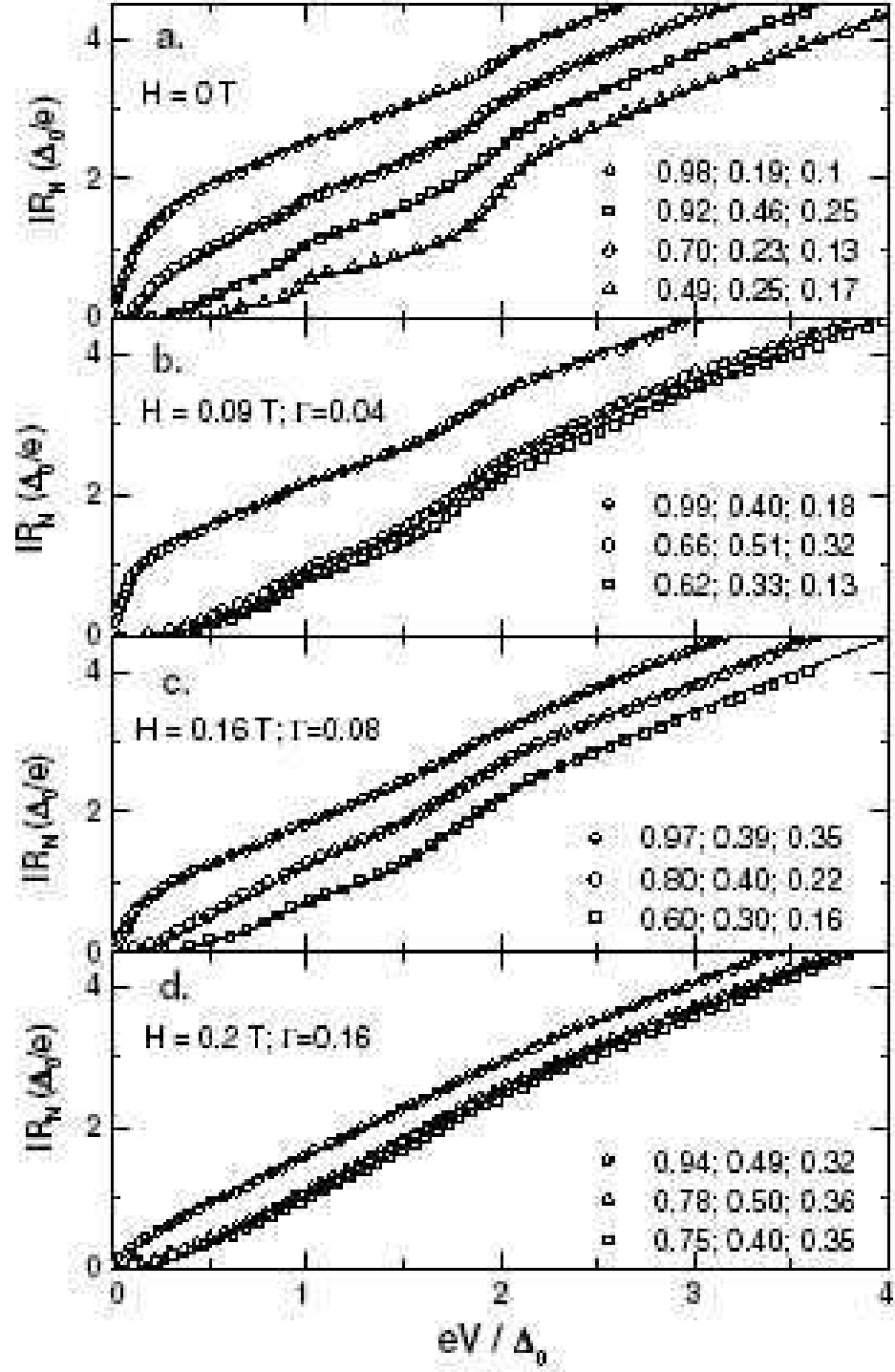


FIG. 16: Comparison of theoretical (lines) and experimental (symbols) single-atom contact I-V curves. Theoretical curves correspond to the constant pair breaking model. Note that the expected field dependence of $\Gamma \propto H^2$ (equ.8) within this model is not found when trying to reproduce the experiment. The parameters in the lower right corner of each figure are the transmissions through the different channels used to fit the experimental data. Each line of numbers corresponds to one curve, from top to bottom. Γ is the pair-breaking parameter defined in the text.

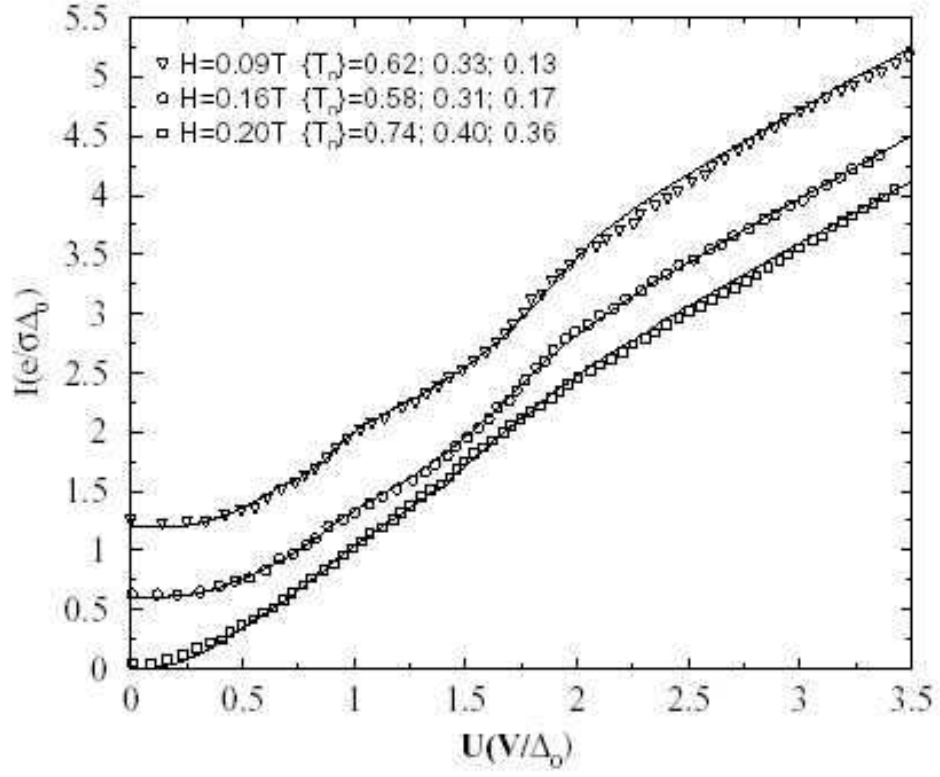


FIG. 17: Comparison of several theoretical (lines) and experimental (points) atomic size contact I-V curves (data are shifted for clarity). Theoretical curves, calculated using the VRPB model, correspond to a geometry with $L = 850\text{\AA}$, $\alpha = 45^\circ$ and $\xi = 325\text{\AA}$.

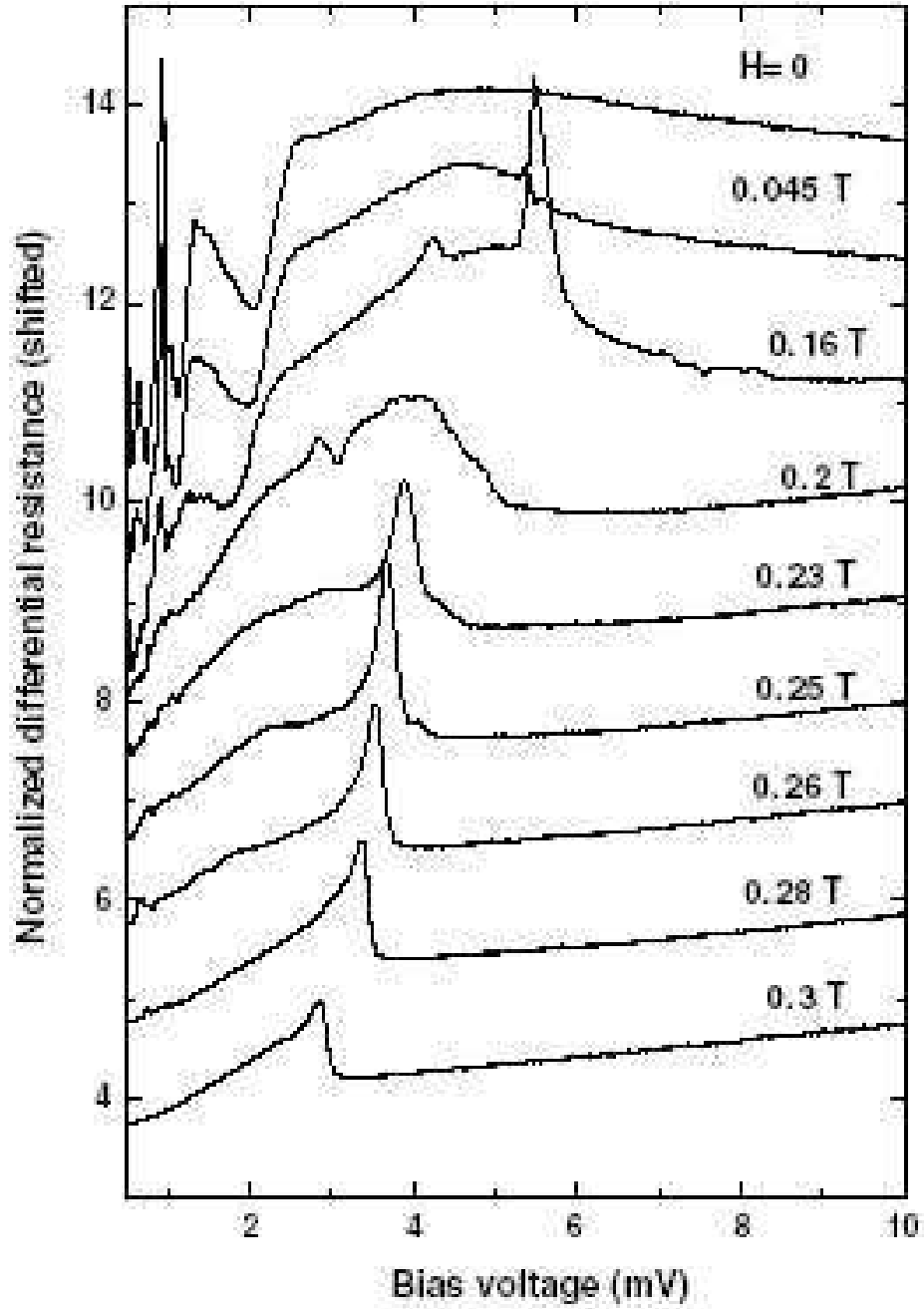


FIG. 18: Nanobridges showing heating effects, also show a striking behavior when the magnetic field is applied. Characteristic peaks appear in the differential resistance, indicative of the nucleation of phase slip centers. Above 0.23T, a single peak structure appears in the conductance, which has been related to non-equilibrium effects. From [46].

V. ADVANCES AND FUTURE PROSPECTS

The nanostructures discussed in this topical review open new interesting fields for basic research and applications. In the following, we will mention some lines in which theoretical and experimental advances could emerge in a near future.

A. Theory and fundamental properties

The properties of nanoscopic superconducting bridges in a magnetic field can be reasonably described using adequate extensions of the BCS theory with bulk values for the gap and other relevant parameters. The electron-electron and electron-phonon interactions should be modified near the contact. The structures discussed here are very well suited to analyze these effects. It would be interesting to estimate the influence of the geometry of the contact on the pairing interactions. Some calculations on the the properties of these nanobridges under magnetic field [18] have raised the question, not yet addressed in published experiments, of the possible confinement of vortices within the smallest possible superconducting structure. The fundamental properties of these vortex states represent, in our opinion, an interesting field for future studies.

The existence of a close contact between a region of the superconducting phase and a bulky normal phase can allow to study small differences between the two phases not included in the BCS theory. An interesting effect is a possible charge transfer between the two phases, derived theoretically from different assumptions[154, 155, 156, 157, 158].

The electron-electron interactions in mesoscopic devices closely connected to bulk electrodes is a topic of significant theoretical interest[159, 160], as these systems show Coulomb blockade features similar to those found in weakly coupled systems[161, 162]. It will be interesting to know if this enhancement of the repulsive interactions modify the superconducting properties of the junction at very low temperatures.

The systems studied here, as discussed earlier, allow us to study superconductors where the gap is not constant throughout the Fermi surface. In these materials, elastic scattering by lattice imperfections is a source of pair breaking processes, playing a similar role to scattering by magnetic impurities in ordinary superconductors. The surface of the sample itself leads to transitions between different bands, or different regions of the Fermi surface[163], and it can change locally the superconducting properties of materials where the gap is not constant, as it is probably the case in MgB_2 [164]. This effect is not yet studied in detail.

B. On the use of superconducting tips

The capability of the method described in section 2 to prepare and characterize at low temperatures STM tips will open new possibilities. Cleanness and atomic sharpness can be guaranteed and easily restored if it is needed during operation. One of the applications recently pointed out is the use of well characterized superconducting tips to do scanning Josephson spectroscopy (SJS)[105, 108]. This technique is a very promising way to obtain important information on the nature of the order parameter of several superconducting materials, especially when a non-conventional behavior opens new challenges [95, 165, 166, 167, 168]. As noted in section 4, the knowledge achieved on the behaviour under magnetic fields of those superconducting tips is also important. As it has been remarked, the electronic density of states at the tip can be changed by modifying its shape, temperature and external magnetic field. This leads to a series of situations, in which the superconducting condensate is confined to a nanometric size region[145], whose relevance goes beyond the phenomena discussed in this Review. In situations where Zeeman effect is important, superconducting tips under magnetic fields should show a spin split density of states [96], becoming a very sensitive probe of the local spin polarization of the sample. Samples with magnetic inhomogeneities such as vortices or ferromagnetic domains will alterate the density of states of the tip while scanning above them, providing a new nanoprobe within the family of the STM.

C. Fluctuations and non-equilibrium effects

During past years, several works have shown that in wires of lateral dimensions even much larger than those of the nanobridges discussed in this review, the resistivity does not go to zero when cooling well below T_c [22, 23, 152, 153, 169]. This is explained by the appearance of quantum phase slip centers, i.e. phase slippage induced by quantum tunnelling through the relevant energy barrier, and not by thermal activation. The fundamental question about the way to include the influence of dissipation [170] in those systems has been the subject of recent debate, and the resistance of the wires has been advanced as the actual source of dissipation[22, 23]. The nanobridges subject of this

review are perfectly joined to the bulk, and represent an interesting alternative way of confining superconductivity, which seems, a priori, to lead to more stable properties at all temperatures. The role of the dissipation should be associated to the proximity to the bulk, instead on the resistance of the structure, and it should be very strong in any case. The large range of temperatures in which a finite zero bias conductance has been observed under magnetic fields [145], contrasts with the observations at zero field and shows that the confinement of the condensate to the smallest length scales increases the influence of fluctuations. The role of quantum fluctuations in explaining this behavior of nanobridges remains an interesting question for future work.

D. The ultimate nanostructure

In a recent experiment G. Rubio Bollinger et al.[61] have used the STM to study the transport between two proximity induced superconducting electrodes. Nanocontacts were produced between two wires of Pb, in an original experimental arrangement which permitted to study many different contacts. The wires were arranged as a cross in such a way as to change easily the position where contact is made by using an in-situ working x-y table. The wires were made of bulk lead covered by a thick layer of lead (approx. 900 nm), ensuring a clean surface, and subsequently evaporating, in-situ on top of the Pb layer, a thin layer of gold, approx. 28 nm in width. In order to minimize inter-diffusion between both elements, the sample was in good thermal contact with a sample holder refrigerated by liquid N₂. Clean single atom point contacts, and atomic chains of gold between the two wires could be routinely made with this technique. In the superconducting phase, multiple Andreev reflection processes occur, allowing for a precise determination of the conducting channels across the single atom point contact. As theoretically expected, in all cases, only a nearly completely opened single channel has been found, not only in single atom point contacts but also in atomic chains consisting of up to five atoms arranged one after the other. To our knowledge the atomic chain fabricated by these authors using a STM is possibly the smallest weak link between two superconductors ever made. It will be interesting to determine if the chain length affects or not the coupling between condensates (Josephson effect).

VI. ACKNOWLEDGMENTS

We are grateful to our colleagues N. Agraït, J.P. Brison, P.C. Canfield, G. Crabtree, J.T. Devreese, J. Flouquet, V.M. Fomin, J.E. Hirsch, A. Levanyuk, K. Maki, V.V. Moshchalkov, O. Naaman, Y. Pogorelov, G. Rubio-Bollinger, G. Schön and R. Villar for their help and stimulating discussions concerning this work at different stages. We acknowledge support from the European Science Foundation programme VORTEX, the MCyT, Spain (grants MAT-2001-1281-C02-0 and MAT2002-0495-C02-01), the Comunidad Autónoma de Madrid, Spain (projects 07N/0039/2002 and 07N/0053/2002), the Swiss National Science Foundation and NCCR MANEP. The Laboratorio de Bajas Temperaturas is associated to the ICMC of the CSIC.

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- [1] W. Meissner and R. Oschenfeld, *Naturwiss.* **21**, 787 (1933).
 - [2] F. London and H. London, *Proc. Roy. Soc.* **A149**, 71 (1935).
 - [3] H. London, *Proc. Roy. Soc.* **A152**, 650 (1935).
 - [4] R. B. Pontius, *Phil. Mag.* **24**, 787 (1937).
 - [5] R. B. Pontius, *Nature* **139**, 1065 (1937).
 - [6] E. T. S. Appleyard, J. A. Bristew, H. London, and A. D. Misener, *Proc. Roy. Soc.* **A170**, 540 (1939).
 - [7] D. Shoenberg, *Proc. Roy. Soc.* **A175**, 49 (1940).
 - [8] V. L. Ginzburg and L. D. Landau, *Zh. Eksperim. i Teor. Fiz.* **20**, 1064 (1950).
 - [9] J. Bardeen, L. N. Cooper, and J. R. Schrieffer, *Phys. Rev.* **108**, 1175 (1957).
 - [10] B. D. Josephson, *Phys. Lett.* **1**, 251 (1962).
 - [11] A. A. Abrikosov, *Sov. Phys. JETP* **5**, 1174 (1957).
 - [12] J. G. Bednorz and K. A. Muller, *Z. Phys. B, Condensed Matter* **64**, 189 (1985).
 - [13] M. Tinkham, *Phys. Rev.* **129**, 2413 (1963).
 - [14] U. Essmann and H. Trauble, *Phys. Lett.* **24A**, 426 (1967).
 - [15] G. Dolan and J. Silcox, *Phys. Rev. Lett.* **30**, 603 (1973).
 - [16] V. V. Moshchalkov, L. Gielen, C. Strunk, R. Jonckheere, X. Qiu, C. van Haesendonck, and Y. Bruynseraede, *Nature* **373**, 319 (1995).
 - [17] A. K. Geim, I. V. Grigorieva, S. V. Dubonos, J. G. S. Lok, J. C. Maan, A. E. Filippov, and F. M. Peeters, *Nature* **390**, 259 (1997).

- [18] V. R. Misko, V. M. Fomin, J. T. Devreese, and V. V. Moshchalkov, Phys. Rev. Lett. **90**, 147003 (2003).
- [19] V. Schweigert and F. Peeters, Phys. Rev. Lett. **83**, 2409 (1999).
- [20] J. J. Palacios, Phys. Rev. Lett. **84**, 1796 (2000).
- [21] D. C. Ralph, C. T. Black, and M. Tinkham, Physical Review Letters **78** (1997).
- [22] C. N. Lau, N. Markovic, M. Bockrath, A. Bezryadin, and M. Tinkham, Physical Review Letters **87** (2001).
- [23] A. Bezryadin, C. N. Lau, and M. Tinkham, Nature **404** (2000).
- [24] A. Kasumov, M. Kociak, M. Ferrier, R. Deblock, S. Gueron, B. Reulet, I. Khodos, O. Stephan, and H. Bouchiat, Physical Review B **68** (2003).
- [25] V. Krstic, S. Roth, M. Burghard, J. Weis, and K. Kern, Physical Review B **68** (2003).
- [26] A. Kasumov, M. Kociak, S. Gueron, B. Reulet, V. Volkov, D. Klinov, and H. Bouchiat, Science **291**, 280 (2001).
- [27] R. Endres, D. Cox., and R. Singh, Rev. of Mod. Phys. **76**, 195 (2004).
- [28] A. Storm, J. van Noort, S. de Vries, and C. Dekker, Appl. Phys. Lett. **79**, 3881 (2001).
- [29] K. Hipps, Science **294**, 536 (2001).
- [30] M. Bockrath, D. Cobden, P. McEuen, N. Chopra, A. Zettl, A. Thess, and R. Smalley, Science **275**, 1922 (1997).
- [31] G. Binnig, H. Rohrer, C. Gerber, and E. Weibel, Appl. Phys. Lett. **40**, 178 (1982).
- [32] G. Binnig, C. F. Quate, and C. Gerber, Phys. Rev. Lett. **56**, 930 (1986).
- [33] G. Rubio-Bollinger, S. R. Bahn, N. Agraït, K. W. Jacobsen, and S. Vieira, Phys. Rev. Lett. **87**, 026101 (2001).
- [34] Y. Martin, C. C. Williams, and H. K. Wickramasinghe, J. of Appl. Phys. **61**, 4723 (1987).
- [35] A. Oral, S. J. Bending, and M. Henini, Appl. Phys. Lett. **69**, 1324 (1996).
- [36] S. Vieira, IBM J. Res. Dev. **30** (1986).
- [37] J. K. Gimzewski and R. Möller, Phys. Rev. B **36**, 1284 (1987).
- [38] N. Agraït, A. L. Yeyati, and J. M. van Ruitenbeek, Physics Reports **377**, 81 (2003).
- [39] N. Agraït, J. G. Rodrigo, C. Sirvent, and S. Vieira, Phys. Rev. B **48**, 8499 (1993).
- [40] J. I. Pascual, J. Mendez, J. Gomez-Herrero, A. M. Baro, N. Garcia, and V. T. Binh, Phys. Rev. Lett. **71**, 12 (1993).
- [41] N. Agraït, J. G. Rodrigo, G. Rubio, C. Sirvent, and S. Vieira, Thin Solid Films **253**, 199 (1994).
- [42] J. I. Pascual, J. Mendez, J. Gomez-Herrero, A. M. Baro, N. Garcia, U. Landman, W. D. Luedtke, E. N. Bogachek, and H. P. Cheng, Science **267**, 5205 (1995).
- [43] J. G. Rodrigo and S. Vieira, Physica C: Superconductivity **404**, 306 (2004).
- [44] H. Hess, R. Robinson, and J. Waszczak, Phys. Rev. Lett. **64**, 2711 (1990).
- [45] S. Pan, E. Hudson, and J. Davis, Applied Phys. Lett. **73**, 2992 (1998).
- [46] H. Suderow and S. Vieira, Physics Letters A **275**, 299 (2000).
- [47] N. Moussy, H. Courtois, and B. Pannetier, Rev. Sci. Instrum. **72**, 128 (2001).
- [48] H. Suderow, M. Crespo, P. Martínez-Samper, J. G. Rodrigo, G. Rubio-Bollinger, S. Vieira, N. Luchier, J. P. Brison, and P. C. Canfield, Physica C **369**, 106 (2002).
- [49] P. Martínez-Samper, J. G. Rodrigo, N. Agraït, R. Grande, and S. Vieira, Physica C **332**, 450 (2000).
- [50] N. Agraït, G. Rubio, and S. Vieira, Phys. Rev. Lett. **74**, 3995 (1995).
- [51] C. Untiedt, G. Rubio, S. Vieira, and N. Agraït, Phys. Rev. B **56**, 2154 (1997).
- [52] J. G. Rodrigo, A. García-Martín, J. J. Sáenz, and S. Vieira, Physical Review Letters **88** (2002).
- [53] U. Landman, W. D. Luedtke, N. A. Burnham, and R. J. Colton, Science **248**, 454 (1990).
- [54] C. A. Stafford, D. Baeriswyl, and J. Burki, Phys. Rev. Lett. **79**, 283 (1997).
- [55] G. Rubio, N. Agraït, and S. Vieira, Phys. Rev. Lett. **76**, 2302 (1996).
- [56] A. Yanson, G. Rubio-Bollinger, H. van den Brom, N. Agraït, and J. van Ruitenbeek, Nature **395**, 783 (1998).
- [57] Landauer, Revista **9**, 1364 (1959).
- [58] D. Wharam, T. Thornton, R. Newbury, M. Pepper, H. Ahmed, J. Frost, D. Hasko, D. Peacock, D. Ritchie, and G. Jones, J. Phys.:Condens. Matter **21**, L209 (1988).
- [59] E. Scheer, P. Joyez, D. Esteve, C. Urbina, and M. H. Devoret, Phys. Rev. Lett. **78**, 3535 (1997).
- [60] E. Scheer, N. Agraït, J. Cuevas, A. Levy-Leyati, B. Ludolph, A. Martín-Rodero, G. Rubio-Bollinger, J. van Ruitenbeek, and C. Urbina, Nature **394**, 154 (1998).
- [61] G. Rubio-Bollinger, C. de las Heras, E. Bascones, N. Agraït, F. Guinea, and S. Vieira, Phys. Rev. B **67**, 121407 (2003).
- [62] Y. Sharvin, Sov. Phys.-JETP **21**, 655656 (1965).
- [63] Z. Gai, X. Li, B. Gao, R. G. Zhao, W. S. Yang, and J. W. M. Frenken, Phys. Rev. B **58**, 2185 (1998).
- [64] J. G. Rodrigo, H. Suderow, and S. Vieira, Unpublished (2004), these data represent the current state of the art of STS on lead nanostructures at the low temperature laboratory, in the Universidad Autonoma de Madrid.
- [65] E. Wolf, *Principles of Electron Tunneling Spectroscopy* (Oxford University Press, Oxford, 1989).
- [66] A. F. Andreev, Soviet Phys. JETP **19**, 1228 (1964).
- [67] S. N. Artemenko, A. F. Volkov, and A. V. Zaitsev, JETP Lett. **28**, 589 (1978).
- [68] S. N. Artemenko, A. F. Volkov, and A. V. Zaitsev, Sov. Phys. JETP **49**, 924 (1979).
- [69] S. N. Artemenko, A. F. Volkov, and A. V. Zaitsev, Solid St. Commun. **30**, 771 (1979).
- [70] A. V. Zaitsev, Sov. Phys. JETP **51**, 111 (1980).
- [71] P. G. deGennes, *Superconductivity of Metals and Alloys* (Addison-Wesley, New York, 1989).
- [72] G. E. Blonder, M. Tinkham, and T. M. Klapwijk, Phys. Rev. B **25**, 4515 (1982).
- [73] M. Octavio, M. Tinkham, G. E. Blonder, and T. M. Klapwijk, Phys. Rev. B **27**, 6739 (1983).
- [74] D. Averin and A. Bardas, Phys. Rev. Lett. **75**, 1831 (1995).

- [75] J. C. Cuevas, A. Martín-Rodero, and A. Levy-Yeyati, Phys. Rev. B **54**, 7366 (1996).
- [76] M. Octavio, W. Skocpol, and M. Tinkham, Phys. Rev. B **17**, 159 (1978).
- [77] E. Bascones and F. Guinea, Phys. Rev. B **65**, 174505 (2002).
- [78] A. Bardas and D. Averin, Phys. Rev. Lett. **79**, 3482 (1997).
- [79] B. D. Josephson, Adv. Phys. **14**, 419 (1965).
- [80] A. Barone and G. Paterno, *Physics and Applications of the Josephson Effect* (Wiley, New York, 1982).
- [81] V. Ambegaokar and A. Baratoff, Phys. Rev. Lett. **10**, 486 (1963).
- [82] K. K. Likharev, Rev. Mod. Phys. **51**, 101 (1979).
- [83] I. Kulik and A. Omelyanchuk, JETP Lett. **21**, 96 (1975).
- [84] C. Beenakker and H. van Houten, Phys. Rev. Lett. **66**, 3056 (1991).
- [85] C. Beenakker, Phys. Rev. Lett. **67**, 3836 (1991).
- [86] M. Ivanchenko and L. A. Zilberman, Sov. Phys. JETP **28**, 1272 (1969).
- [87] Y. Harada, H. Takayanagi, and A. A. Odintsov, Phys. Rev. B **54**, 6608 (1996).
- [88] J. M. Martinis and R. L. Kautz, Phys. Rev. Lett. **63**, 1507 (1989).
- [89] G. L. Ingold, H. Grabert, and U. Eberhardt, Phys. Rev. B **50**, 395 (1994).
- [90] D. Vion, M. Gotz, P. Joyez, D. Esteve, and M. H. Devoret, Phys. Rev. Lett. **77**, 3435 (1996).
- [91] M. Tinkham, *Introduction to Superconductivity* (McGraw International, Singapore, 1996).
- [92] J. G. Rodrigo, H. Suderow, and S. Vieira, Submitted to European Physical Journal B (2004).
- [93] C. Renner, A. D. Kent, P. Niedermann, O. Fischer, and F. Levy, Phys. Rev. Lett. **67**, 1650 (1991).
- [94] H. Suderow, P. Martínez-Samper, N. Luchier, J. P. Brison, S. Vieira, and P. C. Canfield, Phys. Rev. B **64**, 02503 (2001).
- [95] H. Suderow, S. Vieira, J. D. Strand, S. Budko, and P. C. Canfield, Phys. Rev. B **69**, 060504 (2004).
- [96] R. Mersevey and P. Tedrow, Phys. Rep. **238**, 173 (1994).
- [97] R. C. Dynes, V. Narayanamurti, and J. P. Garno, Phys. Rev. Lett. **41**, 1509 (1978).
- [98] B. L. Blackford and R. H. March, Phys. Rev. **186**, 397 (1969).
- [99] G. I. Lykken, A. L. Geiger, K. S. Dy, and E. N. Mitchell, Phys. Rev. B **4**, 1523 (1971).
- [100] P. G. Tomlinson and J. P. Carbotte, Phys. Rev. B **13**, 4738 (1976).
- [101] J. Short and J. Wolfe, Phys. Rev. Lett. **85**, 5198 (2000).
- [102] G. Eliashberg, Zh. E ksp. Teor. Fiz. **38**, 966 (1960).
- [103] W. L. McMillan and J. M. Rowell, Phys. Rev. Lett. **14**, 108 (1965).
- [104] J. G. Rodrigo, N. Agraït, C. Sirvent, and S. Vieira, Phys. Rev. B **50**, 7177 (1994).
- [105] O. Naaman, W. Teizer, and R. Dynes, Phys. Rev. Lett. **87**, 97004 (2001).
- [106] O. Naaman and R. Dynes, Solid State Commun. **129**, 299 (2004).
- [107] O. Naaman, R. C. Dynes, and E. Bucher, Int. J. Mod. Phys. B **17**, 3569 (2003).
- [108] J. Smakov, I. Martin, and A. Balatsky, Phys. Rev. B **64**, 212506 (2001).
- [109] A. Steinbach, P. Joyez, A. Cottet, D. Esteve, M. H. Devoret, M. E. Huber, and J. M. Martinis, Phys. Rev. Lett. **87**, 137003 (2001).
- [110] J. G. Rodrigo, N. Agraït, and S. Vieira, Phys. Rev. B **50**, 12788 (1994).
- [111] G. Rubio-Bollinger, H. Suderow, and S. Vieira, Phys. Rev. Lett. **86**, 5582 (2001).
- [112] E. Boaknin, M. A. Tanatar, J. Paglione, D. Hawthorn, F. Ronning, R. W. Hill, M. Sutherland, L. Taillefer, J. Sonier, S. M. Hayden, et al., Phys. Rev. Lett. **90**, 117003 (2003).
- [113] T. Yokoya, T. Kiss, A. Chainani, S. Shin, M. Nohara, and H. Takagi, Science **294**, 2518 (2001).
- [114] O. Naaman, W. Teizer, and R. Dynes, Rev. Sci. Instrum. **72**, 1688 (2001).
- [115] J. G. Rodrigo, N. Agraït, and S. Vieira, Phys. Rev. B **50**, 374 (1994).
- [116] H. Suderow, E. Bascones, W. Belzig, F. Guinea, and S. Vieira, Europhysics Letters **50**, 749 (2000).
- [117] M. F. Goffman, R. Cron, A. L. Yeyati, P. Joyez, M. H. Devoret, D. Esteve, and C. Urbina, Phys. Rev. Lett. **85**, 170 (2000).
- [118] K. Flensberg and J. B. Hansen, Phys. Rev. B **40**, 8693 (1989).
- [119] A. M. Duif, A. G. M. Jansen, and P. Wyder, J. Magn. Magn. Mater. **63-64**, 664 (1987).
- [120] A. M. Duif, A. G. M. Jansen, and P. Wyder, J. Phys. Condens. Matter **1**, 3157 (1989).
- [121] A. G. M. Jansen, A. van Gelder, and P. Wyder, J. Phys. C **13**, 6073 (1980).
- [122] M. Poza, E. Bascones, J. G. Rodrigo, N. Agraït, S. Vieira, and F. Guinea, Phys. Rev. B **58**, 11173 (1998).
- [123] P. W. Anderson, J. Phys. Chem. Sol. **11**, 26 (1959).
- [124] K. Maki, *Superconductivity* (Marcel Dekker Inc., New York, 1966), p. 1035.
- [125] A. Abrikosov and L. Gorkov, Sov. Phys. JETP **12**, 1243 (1961).
- [126] E. Bascones, Ph.D. thesis, Universidad Autónoma de Madrid (2000).
- [127] G. Eilenberger, Z. Phys. **214**, 195 (1968).
- [128] J. Rammer and H. Smith, Rev. Mod. Phys. **58**, 323 (1986).
- [129] K. D. Usadel, Phys. Rev. Lett. **25**, 507 (1970).
- [130] W. Belzig, F. Wilhelm, C. Bruder, G. Schön, and A. Zaikin, Superlattices and Microstructures **25**, 1251 (1999).
- [131] A. Golubov and M. Kupriyanov, J. of Low. Temp. Phys. **70**, 83 (1988).
- [132] T. Stoof and Y. Nazarov, Phys. Rev. B **53**, 14496 (1996).
- [133] A. Geim, S. V. Dubonos, J. G. S. Lok, M. Henin, and J. Maan, Nature **396**, 6707 (1998).
- [134] K. Maki, Prog. Theor. Phys. **32**, 29 (1964).

- [135] J. J. Palacios, Phys. Rev. B **58**, R5948 (1998).
- [136] A. K. Geim, S. V. Dubonos, J. J. Palacios, I. V. Grigorieva, M. Henini, and J. J. Schermer, Phys. Rev. Lett. **85**, 1528 (2000).
- [137] B. J. Baelus and F. M. Peeters, Phys. Rev. B. **65**, 104515 (2002).
- [138] V. R. Misko, V. M. Fomin, and J. T. Devreese, Phys. Rev. B **64**, 014517 (2001).
- [139] V. Misko, V. Fomin, and J. Devreese, Physica C **369**, 356 (2002).
- [140] H. Suderow, E. Bascones, A. Izquierdo, F. Guinea, and S. Vieira, Phys. Rev. B **65** (2002).
- [141] H. Suderow, A. Izquierdo, and S. Vieira, Physica C **332**, 327 (2000).
- [142] T. Rasing, H. W. M. Salemink, P. Wyder, and S. Strassler, Phys. Rev. B **23**, 4470 (1981).
- [143] J. Daams, H. Zarate, and J. Carbotte, Phys. Rev. B **30**, 2577 (1984).
- [144] E. Scheer, J. C. Cuevas, A. L. Yeyati, A. Martín-Rodero, P. Joyez, M. Devoret, D. Esteve, and C. Urbina, Physica B **280**, 425 (2000).
- [145] J. G. Rodrigo, H. Suderow, and S. Vieira, Phys. Stat. Sol. (b) **237**, 386 (2003).
- [146] A. Schmid and G. Schön, Phys. Rev. Lett. **43**, 793 (1979).
- [147] J. Clarke, U. Eckern, A. Schmid, G. Schön, and M. Tinkham, Phys. Rev. B **20**, 3933 (1979).
- [148] A. Schmid and G. Schön, Phys. Rev. B **21**, 5076 (1980).
- [149] A. Baratoff, Phys. Rev. Lett. **48**, 434 (1982).
- [150] R. Escudero and H. J. T. Smith, Phys. Rev. B **30**, 2527 (1984).
- [151] V. V. Moshchalkov, L. Gielen, G. Neuttiens, C. van Haesendonck, and Y. Bruynseraede, Phys. Rev. B **49**, 15412 (1994), see also comment by I.L. Landau and L. Rinderer, Phys. Rev. B Vol.56, p. 6348 (1997) and reply p. 6352.
- [152] G. R. Boogaard, A. H. Verbruggen, W. Belzig, and T. M. Klapwijk (2004), cond-mat/0401364.
- [153] S. Michotte, S. Mátéfi-Tempfli, L. Piraux, D. Y. Vodolazov, and F. M. Peeters, Phys. Rev. B **69**, 094512 (2004).
- [154] D. I. Khomskii and F. V. Kusmartsev, Phys. Rev. B **46**, 14245 (1992).
- [155] D. Khomskii and A. Freimuth, Phys. Rev. Lett. **75**, 1384 (1995).
- [156] P. Lipavský, K. Morawetz, J. Koláček, J. J. Mares, E. H. Brandt, and M. Schreiber, Phys. Rev. B **69**, 024524 (2004).
- [157] J. E. Hirsch, Phys. Rev. Lett. **92**, 016402 (2004).
- [158] J. E. Hirsch (2004), cond-mat/0312619.
- [159] Y. V. Nazarov, Phys. Rev. Lett. **82**, 1245 (1999).
- [160] D. S. Golubev and A. D. Zaikin, Phys. Rev. Lett. **86**, 4887 (2001).
- [161] F. Guinea and G. Schön, J. Low Temp. Phys. **69**, 219 (1987).
- [162] H. Grabert and M. H. Devoret, eds., *Single Electron Tunneling* (Plenum, New York, 1992).
- [163] E. Bascones and F. Guinea, Phys. Rev. B **64**, 214508 (2001).
- [164] P. Martínez-Samper, J. G. Rodrigo, G. Rubio-Bollinger, H. Suderow, S. Vieira, S. Lee, and S. Tajima, Physica C **385**, 233 (2003).
- [165] F. G. Aliev, J. C. Gomez-Sal, H. Suderow, and R. Villar, eds., *Some modern aspects of the physics of strongly correlated electron systems* (Universidad Autonoma de Madrid, see <http://www.uam.es/inc/summerschool99/>, 2000).
- [166] J. Flouquet, To appear in Progress in Low Temp Phys (????).
- [167] R. Joynt and L. Taillefer, Rev. Mod. Phys. **74**, 235 (2002).
- [168] K. McElroy, R. W. Simmonds, J. E. Hoffman, J. O. D.-H. Lee, H. Eisaki, S. Uchida, and J. C. Davis, Nature **422**, 592 (2003).
- [169] D. Y. Vodolazov, F. M. Peeters, L. Piraux, S. Mátéfi-Tempfli, and S. Michotte, Phys. Rev. Lett. **91**, 157001 (2003).
- [170] A. Schmid, Phys. Rev. B **51**, 1506 (1983).